

PART NUMBER 54LS298BEA-ROCS

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All re-creations are done with the approval of the Original Component Manufacturer. (OCM)

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
 - Class Q Military
 - Class V Space Level

Qualified Suppliers List of Distributors (QSLD)

 Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OCM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.



54LS158, 54LS298

Microcircuits, Digital, Bipolar, Low-Power Schottky TTL, Data Selector/Multiplexer with Three-State Outputs, Monolithic Silicon

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INCH-POUND

MIL-M-38510/309E

10 April 2003

SUPERSEDING

MIL-M-38510/309D

21 June 1985

MILITARY SPECIFICATION

MICROCIRCUITS, DIGITAL, BIPOLAR, LOW-POWER SCHOTTKY TTL, DATA SELECTOR/MULTIPLEXER WITH THREE-STATE OUTPUTS, MONOLITHIC SILICON

Inactive for new design after 18 April 1997.

This specification is approved for use by all Departments and Agencies of the Department of Defense.

1. SCOPE

- 1.1 <u>Scope.</u> This specification covers the detail requirements for monolithic silicon, low-power Schottky TTL, data selector/multiplexer (three-state) logic microcircuits. Two product assurance classes and a choice of case outlines and lead finishes are provided for each type and are reflected in the complete part number. For this product, the requirements of MIL-M-38510 have been superseded by MIL-PRF-38535, (see 6.3).
 - 1.2 Part number. The part number should be in accordance with MIL-PRF-38535, and as specified herein.
 - 1.2.1 Device types. The device types should be as follows:

Device type	<u>Circuit</u>
01	Eight-input data selector/multiplexer, with enable
02	Dual, four-input data selector/multiplexer, with enable
03, 04	Quad, two-input data selector/multiplexer, with enable
05	Eight-input data selector/multiplexer, 3-state outputs with enable
06, 07	Quad, two-input data selector/multiplexer, 3-state outputs with enable
08	Dual, four-input data selector/multiplexer, 3-state outputs with enable
09	Cascadable, quad, two-input data selector/multiplexer, with storage

- 1.2.2 Device class. The device class should be the product assurance level as defined in MIL-PRF-38535.
- 1.2.3 Case outlines. The case outlines should be as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	<u>Terminals</u>	Package style
Е	GDIP1-T16 or CDIP2-T16	16	Dual-in-line
F	GDFP2-F16 or CDFP3-F16	16	Flat pack
Χ	CQCC2-N20	20	Square leadless chip carrier
2	CQCC1-N20	20	Square leadless chip carrier

Beneficial comments (recommendations, additions, deletions) and any pertinent data which may be of use in improving this document should be addressed to: Commander, Defense Supply Center Columbus, ATTN: DSCC-VAS, P. O. Box 3990, Columbus, OH 43216-5000, by using the self addressed Standardization Document Improvement Proposal (DD Form 1426) appearing at the end of this document or by letter.

AMSC N/A FSC 5962

1.3 Absolute maximum ratings.

 	Supply voltage range	-1.5 V at -18 mA to 7.0 V
	Device type 01, 02	55 mW
	Device type 03	
	Device type 04	
	Device type 05	66 mW
	Device type 06, 07	104.5 mW
	Device type 08	
	Device type 09	115.5 mW
	Lead temperature (soldering, 10 seconds)	300°C
	Thermal resistance, junction to case (θ_{JC}) :	
	Cases E, F, X, and 2	(See MIL-STD-1835)
,	Junction temperature (T _J) <u>2</u> /	
1.4	Recommended operating conditions.	
	Supply voltage (V _{CC})	4.5 V dc minimum to 5.5 V dc maximum
;	Supply voltage (V _{CC})	maximum
;	Supply voltage (V _{CC})	maximum 2.0 V
; !	Supply voltage (V _{CC})	maximum 2.0 V
; !	Supply voltage (V _{CC}) Minimum high level input voltage (V _{IH}) Maximum low level input voltage (V _{IL}) Normalized fanout (each output) 3/	maximum 2.0 V 0.7 V
; !	Supply voltage (V _{CC})	maximum 2.0 V 0.7 V 10 maximum
; !	Supply voltage (V _{CC}) Minimum high level input voltage (V _{IH}) Maximum low level input voltage (V _{IL}) Normalized fanout (each output) <u>3</u> / Low logic level High logic level	maximum 2.0 V 0.7 V 10 maximum 20 maximum
;	Supply voltage (V _{CC}) Minimum high level input voltage (V _{IH}) Maximum low level input voltage (V _{IL}) Normalized fanout (each output) <u>3</u> / Low logic level High logic level Case operating temperature range (T _C)	maximum 2.0 V 0.7 V 10 maximum 20 maximum -55° to +125°C
;	Supply voltage (V _{CC}) Minimum high level input voltage (V _{IH}) Maximum low level input voltage (V _{IL}) Normalized fanout (each output) <u>3</u> / Low logic level High logic level Case operating temperature range (T _C) Setup time t _(SETUP) type 09 data to clock	maximum 2.0 V 0.7 V 10 maximum 20 maximum -55° to +125°C 15 ns
;	Supply voltage (V _{CC}) Minimum high level input voltage (V _{IH}) Maximum low level input voltage (V _{IL}) Normalized fanout (each output) <u>3</u> / Low logic level High logic level Case operating temperature range (T _C) Setup time t _(SETUP) type 09 data to clock Setup time t _(SETUP) type 09 word select to clock	maximum 2.0 V 0.7 V 10 maximum 20 maximum -55° to +125°C 15 ns 25 ns
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;	Supply voltage (V _{CC}) Minimum high level input voltage (V _{IH}) Maximum low level input voltage (V _{IL}) Normalized fanout (each output) <u>3</u> / Low logic level High logic level Case operating temperature range (T _C) Setup time t _(SETUP) type 09 data to clock Setup time t _(HOLD) type 09 data to clock Hold time t _(HOLD) type 09 data to clock	maximum 2.0 V 0.7 V 10 maximum 20 maximum -55° to +125°C 15 ns 25 ns 5 ns 0 ns

^{1/} Must withstand the added P_D due to short-circuit test (e.g., I_{OS}). 2/ Maximum junction temperature shall not be exceeded except for allowable short duration burn-in screening conditions in accordance with MIL-PRF-38535.

^{3/} Device will fanout in both high and low levels to the specified number of data inputs on the same device type as that being tested.

2. APPLICABLE DOCUMENTS

2.1 Government documents.

2.1.1 <u>Specifications and Standards</u>. The following specifications and standards form a part of this specification to the extent specified herein. Unless otherwise specified, the issues of these documents shall be those listed in the issue of the Departments of Defense Index of Specifications and Standards (DODISS) and supplement thereto, cited in the solicitation.

SPECIFICATION

DEPARTMENT OF DEFENSE

MIL-PRF-38535 - Integrated Circuits (Microcircuits) Manufacturing, General Specification for.

STANDARDS

DEPARTMENT OF DEFENSE

MIL-STD-883 - Test Method Standard for Microelectronics.

MIL-STD-1835 - Interface Standard Electronic Component Case Outlines

(Unless otherwise indicated, copies of the above specifications and standards are available from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 <u>Order of precedence.</u> In the event of a conflict between the text of this specification and the references cited herein, the text of this document takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

- 3.1 <u>Qualification</u>. Microcircuits furnished under this specification shall be products that are manufactured by a manufacturer authorized by the qualifying activity for listing on the applicable qualified manufacturers list before contract award (see 4.3 and 6.4).
- 3.2 <u>Item requirements</u>. The individual item requirements shall be in accordance with MIL-PRF-38535 and as specified herein or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein.
- 3.3 <u>Design, construction, and physical dimensions.</u> The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein.
 - 3.3.1 Terminal connections. The terminal connections shall be as specified on figure 1.
 - 3.3.2 Logic diagrams. The logic diagrams shall be specified on figure 2.
 - 3.3.3 <u>Truth tables.</u> The truth tables shall be as specified on figure 3.
- 3.3.4 <u>Schematic circuits</u>. The schematic circuits shall be maintained by the manufacturer and made available to the qualifying activity and the preparing activity upon request.
 - 3.3.5 Case outlines. The case outlines shall be as specified in 1.2.3.
 - 3.4 Lead material and finish. The lead material and finish shall be in accordance with MIL-PRF-38535 (see 6.6).

- 3.5 <u>Electrical performance characteristics</u>. The electrical performance characteristics are as specified in table I, and apply over the full recommended case operating temperature range, unless otherwise specified.
- 3.6 <u>Electrical test requirements.</u> The electrical test requirements for each device class shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table III.
 - 3.7 Marking. Marking shall be in accordance with MIL-PRF-38535.
- 3.8 <u>Microcircuit group assignment.</u> The devices covered by this specification shall be in microcircuit group number 11 (see MIL-PRF-38535, appendix A).

4. VERIFICATION

- 4.1 <u>Sampling and inspection.</u> Sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not effect the form, fit, or function as described herein.
- 4.2 <u>Screening.</u> Screening shall be in accordance with MIL-PRF-38535 and shall be conducted on all devices prior to qualification and quality conformance inspection. The following additional criteria shall apply:
 - a. The burn-in test duration, test condition, and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document control by the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015 of MIL-STD-883.
 - b. Interim and final electrical test parameters shall be as specified in table II, except interim electrical parameters test prior to burn-in is optional at the discretion of the manufacturer.
 - c. Additional screening for space level product shall be as specified in MIL-PRF-38535, appendix B.
 - 4.3 Qualification inspection. Qualification inspection shall be in accordance with MIL-PRF-38535.
- 4.4 <u>Technology Conformance inspection (TCI)</u>. Technology conformance inspection shall be in accordance with MIL-PRF-38535 and herein for groups A, B, C, and D inspections (see 4.4.1 through 4.4.4).
 - 4.4.1 Group A inspection. Group A inspection shall be in accordance with table III of MIL-PRF-38535 and as follows:
 - a. Tests shall be as specified in table II herein.
 - b. Subgroups 4, 5, and 6 shall be omitted.
 - 4.4.2 Group B inspection. Group B inspection shall be in accordance with table II MIL-PRF-38535.

TABLE I. <u>Electrical performance characteristics</u>.

Test	Symbol	Con	Device	Lir	nits	Unit	
			C _C ≤ +125°C rwise specified	types	Min	Max	
High level output voltage	V _{OH}	$V_{IL} = 0.7 \text{ V}$ $V_{CC} = 4.5 \text{ V}$	$I_{OH} =4 \text{ mA}$	01, 02, 03, 04, 09	2.5		V
		V _{IH} = 2.0 V	$I_{OH} = -1.0 \text{ mA}$	05, 06, 07, 08	2.4		V
Low level output voltage	V _{OL1}	V _{CC} = 4.5 V	I _{OL} = 4.0 mA	01, 02, 03, 04, 05, 08, 09		0.40	V
			$I_{OL} = 12 \text{ mA}$	06, 07		0.40	V
Input clamp voltage	V _{IC}	$V_{CC} = 4.5 \text{ V}, I_{IN} = T_{C} = +25^{\circ}\text{C}$	-18 mA,	All		-1.5	٧
Low level input current at data inputs	I _{IL1}	$V_{CC} = 5.5 \text{ V}, V_{IN} =$	= 0.4 V	01, 05	0	72	mA
Low level input current at select or strobe	I _{IL2}			01, 05	0	40	mA
Low level input current at A, B, or C	I _{IL3}			01, 05	0	40	mA
Low level input current	I _{IL1}			02, 08	0	40	mA
				09	03	40	
Low level input current at A, B, or C	I _{IL1}			03, 04	0	44	mA
Low level input current at select or strobe	I _{IL2}			03, 04	0	88	mA
Low level input current at A, B, or output control	I _{IL1}			06, 07	0	44	mA
Low level input current	I _{IL2}	1		06	0	88	mA
at select				07	0	80	
High level input current	I _{IH1}	$V_{CC} = 5.5 \text{ V}, V_{IN} =$	= 2.7 V	01, 02, 05, 08, 09		20	μΑ
	I _{IH2}	$V_{CC} = 5.5 \text{ V}, V_{IN} =$	= 7.0 V	01, 02, 05, 08		100	μΑ
	I _{IH2}	$V_{CC} = 5.5 \text{ V}, V_{IN} =$	= 5.5 V	09		100	μΑ
High level input current at A or B	I _{IH1}	V _{CC} = 5.5 V, V _{IN} =	= 2.7 V	03, 04		20	μΑ
5.7.0.2	I _{IH2}	V _{CC} = 5.5 V, V _{IN} =	= 7.0 V			100	μΑ
High level input current at strobe or select	I _{IH3}	V _{CC} = 5.5 V, V _{IN} =	= 2.7 V	03, 04		40	μΑ
4. 0.1050 01 001001	I _{IH4}	V _{CC} = 5.5 V, V _{IN} =	= 7.0 V			200	μΑ
High level input current at A, B, or output control	I _{IH1}	V _{CC} = 5.5 V, V _{IN} =	= 2.7 V	06, 07		20	μΑ
acri, b, or output control	I _{IH2}	V _{CC} = 5.5 V, V _{IN} =	= 7.0 V			100	μΑ

TABLE I. <u>Electrical performance characteristics</u> - Continued.

Test	Symbol	Cond	Device	Lir	nits	Unit	
		-55°C ≤ T ₀	_C ≤ +125°C	types	Min	Max	
			vise specified				
High level input current at select	I _{IH3}	$V_{CC} = 5.5 \text{ V}, V_{IN} = 2.7 \text{ V}$		06, 07		40	μΑ
	I _{IH4}	$V_{CC} = 5.5 \text{ V}, V_{IN} = 3.5 \text{ V}$	7.0 V			200	μΑ
Off-state output current	I _{OZH}	$V_{CC} = 5.5 \text{ V}, V_{O} = 2$	2.7 V	05, 06,		20	μΑ
high level voltage applied				07, 08			
Off-state output current low level voltage applied	I _{OZL}	$V_{CC} = 5.5 \text{ V}, V_{O} = 0$).4 V	05, 06, 07, 08		-20	μΑ
Short circuit output	I _{OS}	V _{CC} = 5.5 V, 1/		01,02,03,	-15	-100	mA
current	.03	V _{OUT} = GND		04, 09			
		1001 0.12		05,06,07,	-15	-130	
				08	.0	100	
Supply current	I _{CC1}	V _{CC} = 5.5 V	V _{IN} (data) = 5.5 V	01		10	mA
	1001		$V_{IN}(data) = GND$	02		10	
			- m(aana)	09		21	
	I _{CC1}	V _{CC} = 5.5 V, V _{IN} (data) = 5.5 V		03		16	mA
	I _{CC1}	V _{CC} = 5.5 V, V _{IN} (data) = 5.5 V		04		8	mA
	I _{CC1}	$V_{CC} = 5.5 \text{ V}, V_{IN}(\text{da})$ $V_{IN}(\text{strobe}) = \text{GND}$	ata) = 5.5 V	05		10	mA
	I _{CC2}	$V_{CC} = 5.5 \text{ V}, V_{IN}(\text{date})$ $V_{IN}(\text{strobe}) = 5.5 \text{ V}$	ata) = 5.5 V	05		12	mA
	I _{CC1}	$V_{CC} = 5.5 \text{ V}, V_{IN}(da)$	ata) = 5.5 V	06		12	mA
		V _{IN} (output control)	=	07		15	
	I _{CC2}	$V_{CC} = 5.5 \text{ V}, V_{IN}(da)$		06		18	mA
		V _{IN} (output control)	=	07		9	
	I _{CC3}	$V_{CC} = 5.5 \text{ V},$ $V_{IN}(\text{output control})$		06, 07		19	mA
	I _{CC1}	$V_{CC} = 5.5 \text{ V}, V_{IN}(\text{da})$ $V_{IN}(\text{output control})$	nta) = GND	08		12	mA
	I _{CC2}	$V_{CC} = 5.5 \text{ V}, V_{IN}(\text{day}$ $V_{IN}(\text{output control})$	ata) = GND	08		14	mA
Propagation delay time,	t _{PLH1}	$V_{CC} = 5.0 \text{ V}, C_L = 5$		01	3	56	ns
low to high level output	YFLN1	$R_L = $ See figure 5.	70 PI ±10/0	02	3	30	110
from data input to Y		TIL = OUS liguie 3.		03	3	29	
nom data input to 1				04	3	26	
				05	3	50	
				06, 07	3	35	
					3		
				09	3	43	
				08	3	45	

 $[\]underline{1}/$ Not more than one output should be shorted at one time.

TABLE I. <u>Electrical performance characteristics</u> - Continued.

Test	Symbol	Conditions	Device	Lin	nits	Unit
1631	Symbol	-55°C ≤ T _C ≤ +125°C	types	Min	Max	Offic
		unless otherwise specified	1,700		Max	
Propagation delay time,	t _{PHL1}	$V_{CC} = 5.0 \text{ V}, C_L = 50 \text{ pF} \pm 10\%$	01, 02	3	47	ns
high to low level output		R _L = See figure 5.	03	3	29	
from data input to Y			04	3	26	
			05	3	50	
			06, 07	3	35	
			09	3	48	
			08	3	38	
Propagation delay time,	t _{PLH2}		01	3	39	ns
low to high level output			05	3	30	
from data to W						
Propagation delay time,	t _{PHL2}		01	3	38	ns
high to low level output			03	3	30	
from data to W						
Propagation delay time,	t _{PLH3}		01	3	71	ns
low to high level output			02	3	44	
from strobe to Y			03	3	38	
			04	3	33	
Propagation delay time,	t _{PHL3}		01, 02	3	56	ns
high to low level output			03	3	39	
from strobe to Y			04	3	35	
Propagation delay time,	t _{PLH4}		01	3	44	ns
low to high level output						
from strobe to W						
Propagation delay time,	t _{PHL4}		01	3	53	ns
high to low level output						
from strobe to W						
Propagation delay time,	t _{PLH5}		01	3	72	ns
high to low level output			02	3	51	
from select to Y			03	3	42	
			04	3	38	
			05, 08	3	75	
			06, 07	3	39	
Propagation delay time,	t _{PHL5}		01	3	53	ns
high to low level output			02	3	65	
from select to Y			03	3	48	
			04	3	44	
			05	3	75	
			06, 07	3	39	
			08	3	56	

TABLE I. <u>Electrical performance characteristics</u> - Continued.

Test	Symbol	Conditions	Device	Lin	nits	Unit
		-55°C ≤ T _C ≤ +125°C unless otherwise specified	types	Min	Max	
Propagation delay time,	t _{PLH6}	$V_{CC} = 5.0 \text{ V}, C_L = 50 \text{ pF} \pm 10\%$	01	3	42	ns
low to high level output		R _L = See figure 5.	05	3	57	
from select to W		-				
Propagation delay time,	t _{PHL6}		01	3	56	ns
high to low level output			05	3	57	
from select to W						
Enable time to high level	t _{PZH1}		05	3	75	ns
output from strobe to Y						
Enable time to high level	t _{PZH2}		05	3	48	ns
output from strobe to W						
Enable time to high level	t _{PZH3}		06, 07	3	53	ns
output from output			08	3	69	
control to Y						
Enable time to low level	t _{PZL1}		05	3	68	ns
output from strobe to Y						
Enable time to low level	t _{PZL2}		05	3	68	ns
output from strobe to W						
Enable time to low level	t _{PZL3}		06, 07	3	53	ns
output from output			08	3	42	
control to Y						
Disable time from high	t _{PHZ1}	$V_{CC} = 5.0 \text{ V}, C_L = 15 \text{ pF minimum}$	05	3	75	ns
level output, from		R _L = See figure 5.				
strobe to Y						
Disable time from high	t _{PHZ2}		05	3	90	ns
level output, from						
strobe to W						
Disable time from high	t _{PHZ3}		06, 07	3	53	ns
level output, from output			08	3	69	
control to Y					45	
Disable time from low	t _{PLZ1}		05	3	45	ns
level output, from						
strobe to Y					45	
Disable time from low	t _{PLZ2}		05	3	45	ns
level output, from						
strobe to W	4	-	00.07		4.5	
Disable time from low	t _{PLZ3}		06, 07	3	45	ns
level output, from output			08	3	48	
control to Y						

TABLE II. Electrical test requirements.

	Subgroups	(see table III)
MIL-PRF-38535	Class S	Class B
test requirements	devices	devices
Interim electrical parameters	1	1
Final electrical test parameters	1*, 2, 3, 7, 9, 10, 11	1*, 2, 3, 7, 9
Group A test requirements	1, 2, 3, 7, 8, 9, 10, 11	1, 2, 3, 7, 8, 9, 10, 11
Group B test requirements when using the method 5005 QCI option	1, 2, 3, 7, 8, 9, 10, 11	N/A
Group C end-point electrical parameters	1, 2, 3, 7, 8 9, 10, 11	1, 2, 3
Group D end-point electrical parameters	1, 2, 3	1, 2, 3

^{*}PDA applies to subgroup 1.

- 4.4.3 Group C inspection. Group C inspection shall be in accordance with table IV of MIL-PRF-38535 and as follows:
 - a. End-point electrical parameters shall be as specified in table II herein.
 - b. The steady-state life test duration, test condition, and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document control by the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005 of MIL-STD-883.
- 4.4.4 <u>Group D inspection.</u> Group D inspection shall be in accordance with table V of MIL-PRF-38535. End-point electrical parameters shall be as specified in table II herein.
 - 4.5 Methods of inspection. Methods of inspection shall be specified and as follows:
- 4.5.1 <u>Voltage and current.</u> All voltages given are referenced to the microcircuit ground terminal. Currents given are conventional and positive when flowing into the referenced terminal.

	Termin	al symbol	Terminal symbol		Terminal symbol		Terminal symbol		Terminal symbol	
	device	e type 01	device	e type 02	pe 02 device type 03		device	type 04	device	type 05
Terminal	Case	Case	Case	Case	Case	Case	Case	Case	Case	Case
number	X, 2	E, F	X, 2	E, F	X, 2	E, F	X, 2	E, F	X, 2	E, F
1	NC	D3	NC	1G	NC	S	NC	S	NC	D3
2	D3	D2	IG	В	S	1A	S	1A	D3	D2
3	D2	D1	В	1C3	1A	1B	1A	1B	D2	D1
4	D1	D0	1C3	1C2	1B	1Y	1B	1Y	D1	D0
5	D0	Y	1C2	1C1	1Y	2A	1Y	2A	D0	Υ
6	NC	W	NC	1C0	NC	2B	NC	2B	NC	W
7	Υ	S	1C1	1Y	2A	2Y	2A	2Y	Υ	S
8	W	GND	1C0	GND	2B	GND	2B	GND	W	GND
9	S	С	1Y	2Y	2Y	3Y	2Y	3Y	S	С
10	GND	В	GND	2C0	GND	3B	GND	3B	GND	В
11	NC	А	NC	2C1	NC	3A	NC	3A	NC	Α
12	C	D7	2Y	2C2	3Y	4Y	3Y	4Y	С	D7
13	В	D6	2C0	2C3	3B	4B	3B	4B	В	D6
14	Α	D5	2C1	Α	3A	4A	3A	4A	Α	D5
15	D7	D4	2C2	2G	4Y	G	4Y	G	D7	D4
16	NC	Vcc	NC	Vcc	NC	Vcc	NC	Vcc	NC	Vcc
17	D6		2C3		4B		4B		D6	
18	D5		Α		4A		4A		D5	
19	D4		2G		G		G		D4	
20	V _{CC}		V _{CC}		V _{CC}		V _{CC}		V _{CC}	

FIGURE 1. <u>Terminal connections</u>.

	Termina	Terminal symbol		al symbol	Terminal symbol		Terminal symbol	
	device	type 06	device	device type 07 device type		type 08	device	e type 09
Terminal	Case	Case	Case	Case	Case	Case	Case	Case
number	X, 2	E, F	X, 2	E, F	X, 2	E, F	X, 2	E, F
1	NC	S	NC	S	NC	1G	NC	B2
2	S	1A	S	1A	1G	В	B2	A2
3	1A	1B	1A	1B	В	1C3	A2	A1
4	1B	1Y	1B	1Y	1C3	1C2	A1	B1
5	1Y	2A	1Y	2A	1C2	1C1	B1	C2
6	NC	2B	NC	2B	NC	1C0	NC	D2
7	2A	2Y	2A	2Y	1C1	1Y	C2	D1
8	2B	GND	2B	GND	1C0	GND	D2	GND
9	2Y	3Y	2Y	3Y	1Y	2Y	D1	C1
10	GND	3B	GND	3B	GND	2C0	GND	WS
11	NC	3A	NC	3A	NC	2C1	NC	CP
12	3Y	4Y	3Y	4Y	2Y	2C2	C1	QD
13	3B	4B	3B	4B	2C0	2C3	WS	QC
14	3A	4A	3A	4A	2C1	Α	CP	QB
15	4Y	G	4Y	G	2C2	2G	QD	QA
16	NC	V _{CC}	NC	V _{CC}	NC	V _{CC}	NC	V _{CC}
17	4B		4B		2C3		QC	
18	4A		4A		Α		QB	
19	G		G		2G		QA	
20	Vcc		Vcc		Vcc		Vcc	

FIGURE 1. <u>Terminal connections</u> - Continued.

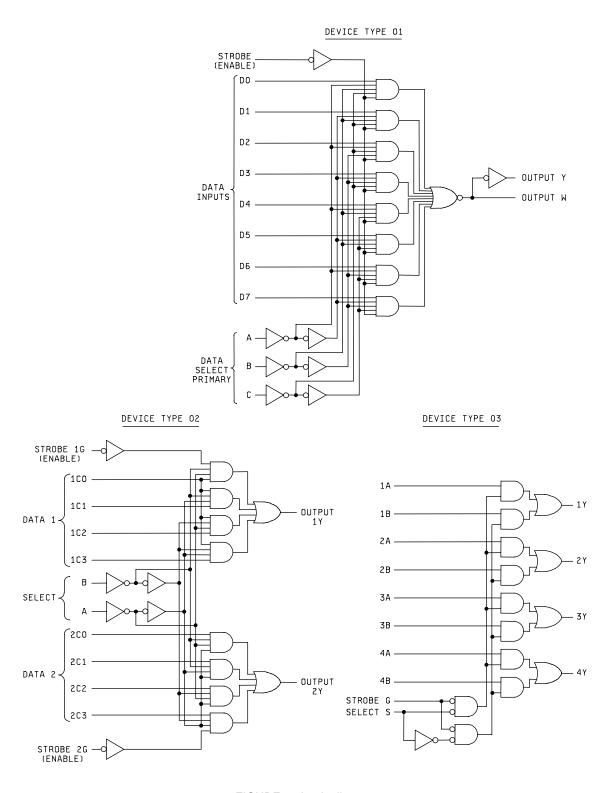
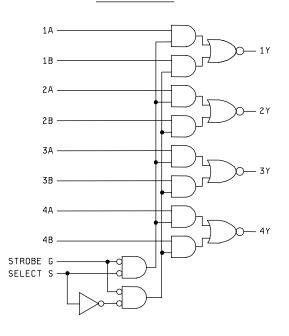


FIGURE 2. Logic diagrams.

DEVICE TYPE 04



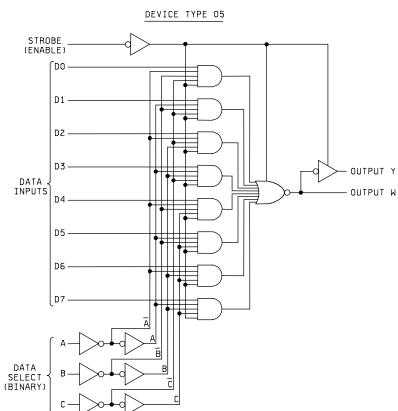
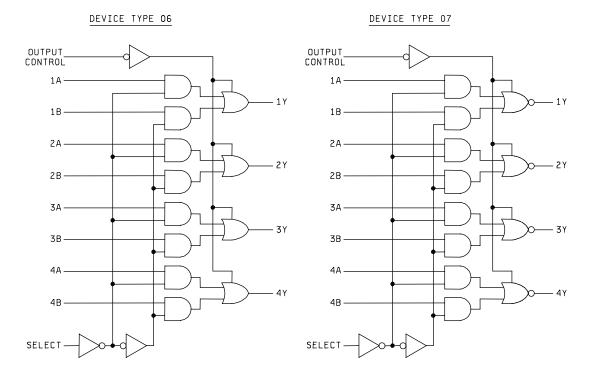


FIGURE 2. Logic diagrams - Continued.



DEVICE TYPE 08

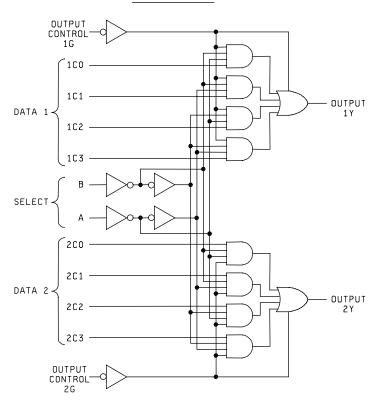


FIGURE 2. Logic diagrams - Continued.

DEVICE TYPE 09

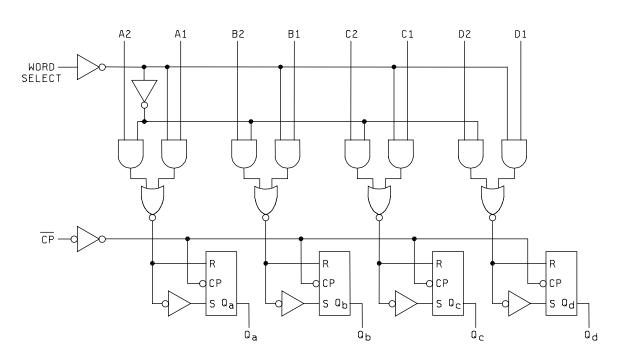


FIGURE 2. Logic diagrams - Continued.

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Device type 01

	IN	OUTI	PUTS		
(SELECT	•	STROBE		
С	В	Α	S	Υ	W
Х	Х	Χ	Н	L	Н
L	L	L	L	D0	D ₀
L	L	Η	L	D1	D1
L	Н	L	L	D2	D2
L	Н	Н	L	D3	D3
Н	L	L	L	D4	D4
Н	L	Н	L	D5	D ₅
Н	Н	L	L	D6	D 6
Н	Н	Н	L	D7	D7

H = high level, L = low level, X = irrelevant. D0, D1 D7 = the level of the D respective input.

Device type 02

	ECT UTS	I	DATA I	NPUTS	6	STROBE	OUTPUT
В	Α	CO	C1	C2	C3	G	Υ
Χ	Х	Χ	Χ	Χ	Χ	Н	L
L	L	L	Χ	Х	Х	L	L
L	L	Η	Χ	Χ	Χ	L	Н
L	Ι	X	L	Х	Х	L	L
L	Н	X	Η	Х	Х	L	Н
Н	L	X	Χ	L	Χ	L	L
Н	L	X	X	Н	Χ	L	Н
Н	Ι	Χ	Χ	Χ	L	L	L
Н	Ι	X	Χ	Х	Н	L	Н

Select inputs A and B are common to both sections.

H = high level, L = low level, X = irrelevant.

Device types 03 and 04

	INPUTS			OUT	PUT Y
STROBE	SELECT	Α	В	TYPE 03	TYPE 04
Н	Х	Х	Х	L	Н
L	L	L	Х	L	Н
L	L	Н	Х	Н	L
L	Н	Χ	L	L	Н
L	Н	Х	Н	Н	L

H = high level, L = low level, X = irrelevant.

FIGURE 3. Truth tables.

Device type 05

	IN	IPUTS		OUTP	UTS
	SELECT		STROBE		
С	В	Α	S	Υ	W
Х	Х	Х	Н	Z	Z
L	L	L	L	D0	$\overline{D0}$
L	L	Н	L	D1	D1
L	Н	L	L	D2	D ₂
L	Н	Н	L	D3	D ₃
Н	L	L	L	D4	D4
Н	L	Н	L	D5	D ₅
Н	Н	L	L	D6	D 6
Н	Н	Н	L	D7	D7

H = high logic level, L = low logic level, X = irrelevant, Z = high impedance (off).

D0, D1....D7 = the level of the respective D input.

Device types 06 and 07

	INPUTS	3		OUTP	UT Y
OUTPUT				TYPE	TYPE
CONTROL	SELECT	Α	В	06	07
Н	Х	Х	Х	Z	Z
L	L	L	Х	L	Н
L	L	Н	Х	Н	L
L	Н	Х	L	L	Н
L	Н	Х	Н	Н	L

H = high logic level, L = low logic level, X = irrelevant, Z = high impedance (off).

FIGURE 3. <u>Truth tables</u> - Continued.

Device type 08

SEL	ECT	[DATA I	NPUTS	6	OUTPUT	OUTPUT
INP	UTS					CONTROL	
В	Α	C0	C1	C2	C3	G	Υ
Х	Χ	Х	Χ	Х	Χ	Н	Z
L	L	L	Χ	Х	Χ	L	L
L	Ш	Н	Χ	Χ	Χ	L	Н
L	Η	Χ	L	Χ	Χ	L	L
L	Н	Х	Н	Х	Χ	L	Н
Н	Ш	Χ	Χ	L	Χ	L	L
Н	L	Χ	Χ	Η	Χ	L	Н
Н	Ι	Χ	Χ	Χ	L	L	L
Н	Η	Χ	Χ	Χ	Η	L	Н

Address inputs A and B are common to both sections.

Device type 09

INPL	JTS		OUTI	PUTS	
WORD					
SELECT	CLOCK	Q_A	Q_B	Q_{C}	Q_D
L	\downarrow	a1	b1	c1	d1
Н	\downarrow	a2	b2	c2	d2
Х	Н	Q _{A0}	Q _{B0}	Q _{C0}	Q_{D0}

H = high level (steady state)

L = low level (steady state)

X = irrelevant (any input, including transitions)

 \downarrow = transition from high to low level

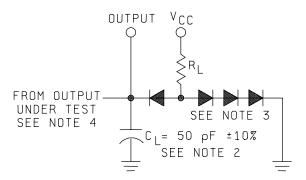
a1, a2, etc. = the level of steady state input at A1, A2, etc. $Q_{A0},\,Q_{B0},\,$ etc. = the level of $Q_A,\,Q_B$ etc, entered on the

most recent ↓ transition of the clock input.

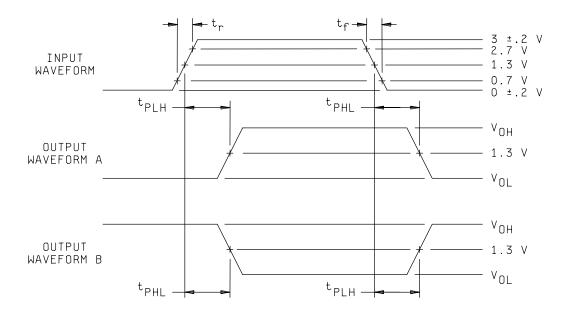
FIGURE 3. <u>Truth tables</u> - Continued.

H = high logic level, L = low logic level, X = irrelevant,

Z = high impedance (off).



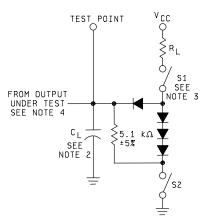
LOAD FOR OUTPUT UNDER TEST



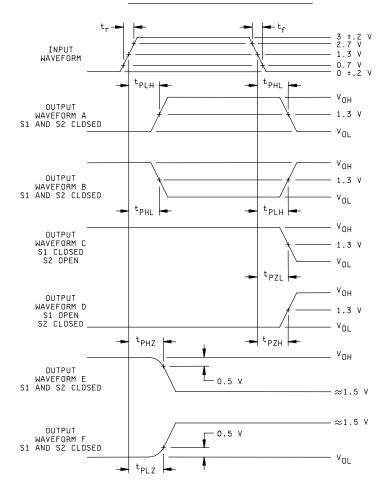
NOTES:

- 1. Input pulse characteristics: PRR \leq 1.0 MHz, $t_r \leq$ 15 ns, $t_f \leq$ 6 ns.
- 2. $C_L = 50 \text{ pF} \pm 10\%$ including probe and jig capacitance.
- 3. $R_L = 2.0 \text{ k}\Omega \pm 5\%$. All diodes are 1N3064 or 1N916.
- 4. Load circuit on a given output is only required where the specific test in table III indicates "OUT" on that output.

FIGURE 4. Switching test for device types 01, 02, 03, and 04.



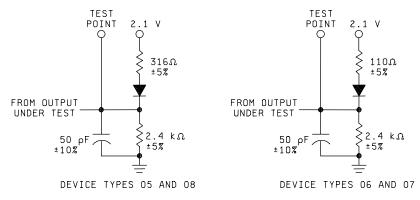
LOAD CIRCUIT FOR THREE STATE OUTPUTS



NOTES:

- 1. Input pulse characteristics: PRR \leq 1.0 MHz, $t_r \leq$ 15 ns, $t_f \leq$ 6 ns.
- 2. C_L = 50 pF ±10% for t_{PLH} , t_{PZL} , and t_{PZH} tests; C_L = 15 pF minimum for t_{PHZ} , and t_{PLZ} tests. C_L includes probe and jig capacitance.
- 3. All diodes are 1N3064 or 1N916. R_L = 2.0 k Ω ±5% for device types 05 and 08, and R_L = 680 Ω ±5% for device types 06 and 07.
- 4. Load circuit on a given output is only required where the specific test in table III indicates "OUT" on that output.

FIGURE 4. Switching test for device types 05, 06, 07, 08 - Continued.



OPTIONAL LOAD CIRCUITS FOR THREE STATE OUTPUTS

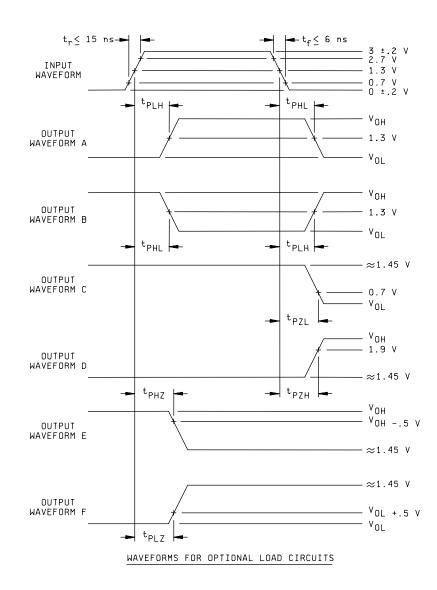
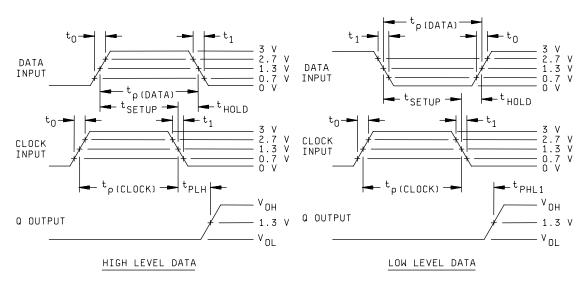
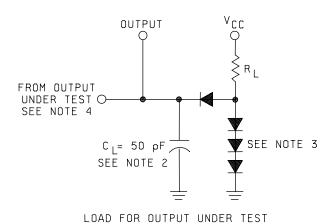


FIGURE 4. Switching test for device types 05, 06, 07, 08 - Continued.



CLOCK TO OUTPUT



NOTES:

- 1. Input pulse characteristics: PRR \leq 1.0 MHz, $t_0 \leq$ 15 ns, $t_l \leq$ 6 ns, $t_P(data) =$ 20 ns, $t_P(clock) =$ 20 ns, $t_{SETUP} =$ 15 ns, and $t_{HOLD} =$ 5 ns.
- 2. $C_L = 50 \text{ pF} \pm 10\%$ including probe and jig capacitance.
- 3. $R_L = 2.0 \text{ k}\Omega \pm 5\%$. All diodes are 1N3064 or equivalent.
- 4. Load circuit on a given output is only required where the specific test in table III indicates "OUT" on that output.

FIGURE 4. Switching test for device type 09 - Continued.

TABLE III. Group A inspection for device type 01. Terminal conditions (pins not designated may be high \geq 2.0 V; low \leq 0.7 V; or open).

						16	Hillinai	COHUILIO	na (hina	Hot des	ngnated	i illay b	e nign ≥	2.0 V, IC	JW ≥ U.1	v, or op	en).						
		MIL-STD-	Cases E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16				
Subgroup	Symbol	883 method	Cases <u>1</u> / 2, X	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20	Measured terminal	Lim	nits	Unit
			Test no.	D3	D2	D1	D0	Υ	W	S	GND	С	В	Α	D7	D6	D5	D4	V _{CC}		Min	Max	
1	1/	3006	1	2.0 V	2.0 V	2.0 V	2.0 V	- 1	4 mA	2.0 V	GND	2.0 V	2.0 V	2.0 V	2.0 V	2.0 V	2.0 V	2.0 V	4.5 V	W	2.5	IVIAX	V
	V _{OH}	3006		2.U V	2.0 V	Z.U V	2.0 V	4 mA	4 IIIA		GIND	0.7 V	0.7 V	0.7 V	2.0 V	2.U V	2.0 V	2.U V	4.5 V	Y	2.5		V
Tc = 25°C	.,		2		-			4 MA	4.0 4	0.7 V											2.5	0.4	
	V _{OL}	3007	3					40.4	4.0 mA	0.7 V		0.7 V	0.7 V	0.7 V						W		0.4	
	. ,,	3007	4	40. 4				4.0 mA		2.0 V		2.0 V	2.0 V	2.0 V						Y		0.4	
	V _{IC}		5	-18 mA																D3		-1.5	
			6		-18 mA	40. 4					- :									D2		- "	
			7			-18 mA														D1			
			8				-18 mA													D0			-
			9							-18 mA										S			-
			10									-18 mA								C		-	:_
			11										-18 mA							В			
			12											-18 mA						Α		"	-
			13								"				-18 mA					D7		"	
			14								"					-18 mA			"	D6		"	
			15								"						-18 mA		"	D5		"	
			16								"							-18 mA	"	D4		"	
	I _{IL1}	3009	17	0.4 V	5.5 V	5.5 V	5.5 V			GND	"	GND	5.5 V	5.5 V	5.5 V	5.5 V	5.5 V	5.5 V	5.5 V	D3	<u>2</u> /	<u>2</u> /	mA
			18	5.5 V	0.4 V	5.5 V							5.5 V	GND					"	D2		"	
		"	19	"	5.5 V	0.4 V							GND	5.5 V	"			"	"	D1		"	"
		"	20	"	"	5.5 V	0.4 V			"			GND	GND	"	"	-		"	D0		"	"
			21	"	"	"	5.5 V			"	"	5.5 V	5.5 V	5.5 V	0.4 V	"			"	D7	"	"	"
		"	22	"	"	"	"			"			5.5 V	GND	5.5 V	0.4 V			"	D6		"	
		"	23	"	"	"	"			"	"		GND	5.5 V		5.5 V	0.4 V		"	D5		"	
		"	24	"	"	"	"			"	"		GND	GND		5.5 V	5.5 V	0.4 V	"	D4	"	"	"
	I_{IL2}	"	25							0.4 V	"								"	S	"	"	
	I_{IL3}	"	26								"	0.4 V							"	С	"	"	
		"	27								"		0.4 V						"	В	"	"	
		"	28								"			0.4 V					"	Α	"	"	
	I _{IH1}	3010	29	2.7 V	GND	GND	GND			5.5 V	"	5.5 V	GND	GND	GND	GND	GND	GND	"	D3		20	μΑ
		"	30	GND	2.7 V	GND							GND	5.5 V		"			"	D2		"	
		"	31	"	GND	2.7 V	"			"	"		5.5 V	GND		"	-		"	D1		"	
			32	"	GND	GND	2.7 V						5.5 V	5.5 V		"	-		"	D0		"	"
		"	33							2.7 V	"								"	S		"	
			34								"	2.7 V								С			
		"	35								"		2.7 V						"	В		"	
			36		L						"			2.7 V						Α		"	"
			37	GND	GND	GND	GND			5.5 V	"	GND	GND	GND	2.7 V	GND	GND	GND	"	D7		"	"
			38			"	"			"	"		GND	5.5 V	GND	2.7 V	GND		"	D6		"	"
			39	"		"	"			"	"	"	5.5 V	GND	- "	GND	2.7 V		"	D5	ļ	"	
	L	- "	40	"		- "	- "			"		"	5.5 V	5.5 V			GND	2.7 V	"	D4		"	"
	I _{IH2}		41	7.0 V		"	"			"	"	5.5 V	GND	GND	"			GND	"	D3		100	μA
			42	GND	7.0 V						"	"	GND	5.5 V					"	D2		"	
		"	43		GND	7.0 V					"	"	5.5 V	GND					"	D1		"	"
		"	44	"	GND	GND	7.0 V						5.5 V	5.5 V	"			"	"	D0	ļ	"	"
			45		ļ					7.0 V	"								"	S	ļ	"	
			46		ļ						"	7.0 V								С	ļ	"	
			47		ļ						"		7.0 V	ļ						В	ļ	"	
			48								"			7.0 V					"	Α		"	
			49	GND	GND	GND	GND			5.5 V	"	GND	GND	GND	7.0 V	GND	GND	GND	"	D7		"	
			50	"		"				"	"		GND	5.5 V	GND	7.0 V	GND		"	D6		"	"
			51		"					"			5.5 V	GND	-	GND	7.0 V		"	D5		- "	
L		."	52	. "		"	."			."			5.5 V	5.5 V	ď	"	GND	7.0 V	"	D4		"	

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See footnotes at end of device type 01.

TABLE III. Group A inspection for device type 01 - Continued.

						Τe	erminal o	conditio	ns (pins	not des	signated	may b	e high ≥	2.0 V; Ic	$w \le 0.7$	V; or op	en).						
		MIL-STD-	Cases E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16				
Subgroup	Symbol	l 883 method	Cases <u>1</u> / 2, X	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20	Measured terminal	Lin	nits	Unit
			Test no.	D3	D2	D1	D0	Υ	W	S	GND	С	В	Α	D7	D6	D5	D4	V_{CC}		Min	Max	
1	Ios	3011	53	GND	GND	GND	5.5 V	GND		GND	=	GND	GND	GND	GND	GND	GND	GND	5.5 V	Υ	-15	-100	mΑ
Tc = 25°C		3011	54	GND	GND	GND	GND		GND	5.5 V	=	GND	GND	GND	GND	GND	GND	GND	"	W	-15	-100	
	I _{CC1}	3005	55	5.5 V	5.5 V	5.5 V	5.5 V			5.5 V	=	5.5 V	5.5 V	5.5 V	5.5 V	5.5 V	5.5 V	5.5 V	"	V _{cc}		10	
2	Same t	ests, termina																					
3	Same t	ests, termina	al conditions	s, and limit	s as subgr	oup 1, exc	ept T _C = -	55°C and \	V _{IC} tests a	re omitted													
7	Func-	3014	56	В	В	В	В	L	Н	Α	GND	В	В	В	В	В	В	В	5.0 V	All			
Tc = 25°C		"	57	Α	Α	Α	Α	"	"	"	"	В	В	В	Α	Α	Α	Α	"	outputs			
	tests	"	58	Α	Α	Α	Α	"	"	"	"	Α	Α	Α	Α	Α	Α	Α	"	"			
		"	59	В	В	В	В	"	"		"	"	"	"	В	В	В	В		"			
		"	60	"	"	"	"	"	"	"	"	"		"	Α	Α	Α	Α	"	"			
			61	"	"	"	"	H	L	В	"	"		"		В	В	В	"				
			62					L	Н	A				В		A						_,	
			63					H	L	В				В								<u>3</u> /	
			64			- "		L	H	A	-:-		В	A			A						
		ï.	65	- "	- "	- "	- "	H	L	В	- :			A						i i			
			66					L	H	A		-		B B				A					
			67		-	-	-	H L	L	B A	,	В		A		-	-		-				
			68 69	A		,		H	H	B	,	В "	A	A					-	,			
			70	"	А	,			H	A	,		-	В					-	,			
			70		A			L H	L	В				В						"			
			72	"	"	Α	"	- ii	Н	A	"		В	A									
			73	"	"	"	"	Н	- ;	В	"		"	A									
			74	"	"	"	Α	Ë	Н	A	"			В						"			
			75	"	"	"	A	H	Ë	В	"			В					"	"			
8	Repeat	subgroup 7		= +125°C :	and $T_c = -$	55°C.						l l					l				l		
9	t _{PLH1}	3003	76				IN	OUT		GND	GND	GND	GND	GND					5.0 V	D0 to Y	3	37	ns
Tc = 25°C		Fig. 4	77			IN		"		"	"	"	GND	5.0 V						D1 to Y			
		"	78		IN			"		"	"	"	5.0 V	GND					"	D2 to Y		"	"
			79	IN				"		"	"		5.0 V	5.0 V					"	D3 to Y		"	"
		"	80					"		"	"	5.0 V	GND	GND				IN		D4 to Y			
			81					"		"	"	"	GND	5.0 V			IN			D5 to Y		"	
		"	82					"		"	"	"	5.0 V	GND		IN			"	D6 to Y	"	"	"
		"	83					"		"	"	"	5.0 V	5.0 V	IN				"	D7 to Y			"
	t _{PHL1}	"	84				IN	=		"	"	GND	GND	GND						D0 to Y		31	
		"	85			IN		"		"	"	"	GND	5.0 V					"	D1 to Y	"	"	"
	1		86		IN			"		"	"	"	5.0 V	GND						D2 to Y	"	- "	"
			87	IN						"			5.0 V	5.0 V						D3 to Y		"	
			88							"		5.0 V	GND	GND				IN		D4 to Y		"	"
			89									- "	GND	5.0 V			IN			D5 to Y		- " -	
	1		90					- "			- "		5.0 V	GND		IN				D6 to Y			
	<u> </u>		91				INI	- "	OUT			OND	5.0 V	5.0 V	IN					D7 to Y	-		-
	t _{PLH2}		92			INI	IN		OUT			GND	GND	GND						D0 to W	-	26	-
	1		93		INI	IN			- "		-	-	GND	5.0 V					-	D1 to W	-		-
			94	INI	IN	-			"	"	"	-	5.0 V	GND						D2 to W			-
			95	IN		-			"		"	5.0 V	5.0 V GND	5.0 V				IN	"	D3 to W	-	"	
	1		96 97						"			3.U V	GND	GND 5.0 V			IN	IIN		D4 to W D5 to W			
	1		98	 	 	1	 		"			-	5.0 V	GND		IN	IIN			D6 to W			
		"	99						"	"	"		5.0 V	5.0 V	IN	IIN				Do to W			
	1	1	99	l	l	L	l		l		I		J.U V	J.0 V	11.4	I	l			ווטווכ	l		

See footnotes at end of device types 01.

TABLE III. Group A inspection for device type 01 - Continued. Terminal conditions (pins not designated may be high > 2.0 V: low < 0.7 V: or open)

							JIIIIIIIII	COHUILIO	no (pine	HOL UC	signated	i iliay L	e nign ∠	2.0 V, I	JW <u>> 0.7</u>	v, 01 0p	Jenj.						
		MIL-STD-	Cases E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16				
Subgroup	Symbol	883 method	Cases <u>1</u> / 2, X	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20	Measured terminal	Lim	iits	Unit
			Test no.	D3	D2	D1	D0	Υ	W	S	GND	С	В	Α	D7	D6	D5	D4	V _{cc}		Min	Max	l
9	t _{PHL2}	3003	100				IN		OUT	GND	GND	GND	GND	GND					5.0 V	D0 to W	3	25	ns
Tc = 25°C		Fig. 4	101			IN			"				GND	5.0 V						D1 to W			"
		"	102		IN				"	"	"		5.0 V	GND					"	D2 to W		=	
		"	103	IN					"	"	"		5.0 V	5.0 V					"	D3 to W			"
		"	104						"	"	"	5.0 V	GND	GND				IN	"	D4 to W		=	"
		"	105						=	=	=	"	GND	5.0 V			IN		-	D5 to W	-	"	-
		"	106						=	=	=		5.0 V	GND		IN			-	D6 to W	-	-	"
		"	107						=	-	-		5.0 V	5.0 V	IN					D7 to W			
	t _{PLH3}	"	108	5.0 V	5.0 V	5.0 V	5.0 V	OUT		IN	"	GND	GND	GND	5.0 V	5.0 V	5.0 V	5.0 V	"	S to Y		47	"
	t _{PHL3}	"	109	5.0 V	5.0 V	5.0 V	5.0 V	OUT		"	"	GND	GND	GND		5.0 V	5.0 V	5.0 V	"	S to Y		37	"
	t _{PLH4}	"	110	GND	GND	GND	GND		OUT	"	"	5.0 V	5.0 V	5.0 V		GND	GND	GND	"	S to W		29	"
	t _{PHL4}	"	111	GND	GND	GND	"		OUT	"	"	5.0 V	5.0 V	5.0 V	"	GND	GND	GND	"	S to W	"	35	"
	t _{PLH5}	"	112			5.0 V	"	OUT		GND	"	GND	GND	IN					"	A to Y	"	48	"
		"	113		5.0 V		"	"		"	"	GND	IN	GND					"	B to Y	"	"	"
		"	114				"	"		=	"	IN	GND	GND				5.0 V	"	C to Y		"	
	t _{PHL5}		115			GND	5.0 V	"		"	"	GND	GND	IN					"	A to Y	-:-	35	
		. "	116		GND		- "	- "		- "	"	GND	IN	GND					"	B to Y		"	
		- "	117					"				IN	GND	GND				GND		C to Y			
	t _{PLH6}		118			GND	"		OUT	"	- "	GND	GND	IN						A to W	-	28	- "
			119		GND		- "		- :	- "	- "	GND	IN	GND						B to W	-	- "	
			120			5.01/			-:-	- "	- "	IN	GND	GND				GND	<u> </u>	C to W			- "
	t _{PHL6}		121		5.01/	5.0 V	GND			- "		GND	GND	IN					<u> </u>	A to W	- "	37	<u> </u>
			122		5.0 V		- "		- :	- "	- "	GND	IN	GND					-:-	B to W	-	- "	- "
		,,	123				"		."	,,	,,	IN	GND	GND				5.0 V		C to W		,,	

Same tests and terminal conditions as for subgroup 9, except $T_C = +125^{\circ}C$ and for following limits: $t_{\text{PLH}1} = 3 \text{ to } 56 \text{ ns}; t_{\text{PLH}2} = 3 \text{ to } 47 \text{ ns}; t_{\text{PLH}2} = 3 \text{ to } 39 \text{ ns}; t_{\text{PLH}2} = 3 \text{ to } 38 \text{ ns}; t_{\text{PLH}3} = 3 \text{ to } 71 \text{ ns}; t_{\text{PHL}3} = 3 \text{ to } 56 \text{ ns}; t_{\text{PLH}4} = 3 \text{ to } 44 \text{ ns}; t_{\text{PHL}4} = 3 \text{ to } 53 \text{ ns}; t_{\text{PLH}5} = 3 \text{ to } 72 \text{ ns}; t_{\text{PLH}5} = 3 \text{ to } 53 \text{ ns}; t_{\text{PLH}6} = 3 \text{ to } 42 \text{ ns}; t_{\text{PHL}6} = 3 \text{ to } 56 \text{ ns}.$

$\underline{2}/\ I_{\text{IL}}$ limits shall be as follows:

			Min/M	lax limits (mA) for circuit		
Test	Α	В	С	D	Е	F	G
I _{IL1}	16/40	12/36	16/40	03/30	002/150	105/345	0/15
I _{IL2 &}	12/36	12/36	16/40	03/30	002/150	16/40	0/15
I _{IL3}					10/34		

 $\underline{3}/$ Inputs: A \geq 2.5 V minimum, B \leq 0.4 V maximum.

Outputs: $H \ge 1.5 \text{ V}, L \le 1.5 \text{ V}.$

Same tests, terminal conditions and limits as for subgroup 10, except $T_C = -55^{\circ}C$.

^{1/} Case X and 2 pins not referenced are NC.

TABLE III. <u>Group A inspection for device type 02</u>. Terminal conditions (pins not designated may be high \geq 2.0 V; low \leq 0.7 V; or open).

Subgraph Subgraph							16	erminai (conaitio	ns (pins	not des	signated	i may b	e nign ≥	2.0 V; I	0.7	v; or op	en).						
Perform Perf			MIL-STD-		1	2							9	10					15	16				
Te-20C Vo. 3008 1 0.7 V 0.7 V 2.0 V 4 MA SMD V 2.0 V V 2.5 V V 2.5 V V V 2.5 V V V V V V V V V	Subgroup	Symbol			2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20		Lim	nits	Unit
Te-20C Vo. 3008 1 0.7 V 0.7 V 2.0 V 4 MA SMD V 2.0 V V 2.5 V V 2.5 V V V 2.5 V V V V V V V V V				Test no	1G	B	1C3	1C2	1C1	1C0	1Y	GND	2Y	2C0	2C1	2C2	2C3	Δ	2G	Voc		Min	Max	1
Tre 28°C	1	Vou	3006				103	102	101				21	200	201	202	200		20		1V		IVIGA	V
Vic. Sept. Sept.		VOH			0.1 V					2.0 V			- 1 mA	201/					0.7.1/					
South Sout	10 - 23 0	V			201/	0.7 V					./ mΔ	"	- III/A	2.0 V				0.7 V	0.7 V			2.0	0.4	-
Victor		V OL			2.0 V						7111/3	"	.1 mΔ						201/					-
18 mA		V	3007		-18 m∆							"	7111/5						2.0 V					
Total 18 mA		VIC			-101117	-18 m∆						"											"	-
B						-10 111/4	-18 m∆					"												
1							1011111	-18 m∆				"												-
10								10 110 1	-18 mA			"												
11									1011111	-18 mA		"												
12										1011111		"		-18 mA										
13												"			-18 mA									
14												"				-18 mA								
15												"					-18 mA							
15 3009 17 0.4 V GND												"						-18 mA		"			"	
18				16								"							-18 mA		2G			
19		I _{IL1}	3009	17	0.4 V	GND						"						GND	GND	5.5 V	1G	2/	2/	mA
1			"	18	GND							"						GND		"			"	
1			"	19	"	5.5 V	0.4 V	5.5 V	5.5 V	5.5 V				5.5 V	5.5 V	5.5 V	5.5 V	5.5 V		"	1C3	-	"	"
1			"	20	"		5.5 V									-				"		-	"	"
Bat 23			"	21	"	GND	"	5.5 V	0.4 V			"				-						-		"
1			"		"		"	"	5.5 V	0.4 V							-			"		-	"	"
Part			"			"	"	"	"	5.5 V		"								"		-	"	"
Part			"		"	"	"	"	"	"		"		5.5 V		"			"	"		"	"	"
1			"		"		"	"	"	"		"								"		"	"	"
1811 3010 29 2.7 V GND			"		"		"	"	"	"		"			5.5 V	5.5 V	0.4 V			"			"	"
No. No.			"		"							"								"		"	"	-
30 GND 2.7V		<u> </u>	"									- "												
1		I _{IH1}	3010																5.5 V				20	μA
1												- "												
1					5.5 V									GND			GND						- "	
1							GND																	
No. No.						5.5 V		GND		0.71/						-			-					
36									GIND					2.71/										
No. St. St.						-	-	,	-	GND		-											,	
38					"	CND	"		"	"				GIND "		271/							"	"
No. No.		1			"		"	"	"	"		"					27 V			"			"	"
He			"		"							"			OIVD	OIVD	Z.1 V		GND	"			"	"
H _{1H2}		1			"		1	1				"	1				1			"			"	"
## 42 GND 7.0 V GND		liho	"		7.0 V							"								"			100	пА
## 43 5.5 V GND 7.0 V GND GND		'Inz	"									"							"	"			"	μ/\
## 44 ## GND GND 7.0 V GND ## ## ## ## ## ## ## 5.5 V ## ## 1C2 ## ## ## ## ## ## ## ## ## ## ## ## ##		1	"				7.0 V	GND	GND	GND		"	1	GND	GND	GND	GND							-
45			"		"							"		"			"		"	"			"	"
46		1	"		"		"			"		"		"	"		"		"	"				"
47			"		"	"	"	"		7.0 V		"		"	"					"			"	"
48		1	"		"	"	"	"	"			"	1	7.0 V	"		"			"			"	"
49			"		"	"	"	"	"	"		"			7.0 V		"		"	"			"	"
SO		1	"		"	GND	"	"	"	"		"		"			"		"	"	2C2		"	"
" 52 " 5.5 V " " " " " " " " " " " " GND 5.5 V " " " " " " " " " " " " " " 2G " " " "			"		"		"	"	"	"		"			GND	GND	7.0 V	GND		"	2C3		"	"
I _{OS} 3011 53 GND GND GND GND GND 5.5 V GND " GND " 1Y -15 -100 mA 3011 54 " " " " GND 5.5 V " " " " " " 2Y -15 -100 "		1	"		"	5.5 V						"						7.0 V		"			"	"
3011 54 " " " " 5.5 V " GND 5.5 V " " " " " " 2Y -15 -100 "			"									"						GND		"			"	
		Ios			GND	GND	GND	GND	GND		GND	"				GND	GND		GND	"				mA
L L _{CC1} 3005 55 " " " GND " " " " V _{CC} 10 "					"	"	"	"	"			"	GND			"	"	"	"	"		-15		"
		I _{CC1}	3005	55	"	"	"	"	"	GND		"		GND	"	"	"	"	"	"	V _{CC}		10	"

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See footnotes at end of device type 02.

TABLE III. Group A inspection for device type 02 - Continued. Terminal conditions (pins not designated may be high $\geq 2.0 \text{ V}$: low $\leq 0.7 \text{ V}$; or open).

3 S 7 F Tc = 25°C	Same te Same te Func-	method	Cases E, F Cases <u>1</u> / 2, X	2	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16				
2 S 3 S 7 F Tc = 25°C ti	Same te Same te Func-	method		2	_						-	-	10			-							1
3 S 7 F Tc = 25°C	Same te Func-				3	4	5	7	8	9	10	12	13	14	15	17	18	19	20	Measured terminal	Lir	nits	Unit
3 S 7 F Tc = 25°C	Same te Func-		Test no.	1G	В	1C3	1C2	1C1	1C0	1Y	GND	2Y	2C0	2C1	2C2	2C3	Α	2G	Vcc		Min	Max	i
3 S 7 F Tc = 25°C	Same te Func-	ests, termina	al conditions	, and limit	s as subgr	oup 1, exc	ept T _C = +	125°C and	V _{IC} tests	are omitte	d.												
Tc = 25°C ti			al conditions																				
		3014	56	Α	Α	Α	Α	Α	Α	L	GND	L	Α	Α	Α	Α	Α	Α	5.0 V	1Y, 2Y			
	tional	"	57	=	В	В	В	В	В	"	-	"	В	В	В	В	В	-	-				
1	tests		58						Α				Α	-	-		-	-	"				
		"	59	В	-	"	-	-	Α	Н	"	Н	Α	-	-	-	-	В					
		"	60	"	"	"	"	"	В	L	"	L	В	"					"				
			61		"	Α	Α	Α	"	"	"	"		Α	Α	Α			"				
			62	A		- "			- "		- "						A	A	- "		_,		
			63	В	- :	- "	-:-		-:-	H	- "	H						В			<u>3</u> /		
			64	В				В		L		L		В		-	D	В					
			65 66	A B	A	"	,	,	,	H	"	H		,			B	A B	-				
		"	67	В		"	В	"	"	r1 I	"	H I		"	В			В					
			68	A	"	"	"	"	"	-	"	-		"	"		Α	A					
			69	В	"	"	"	"	"	H	"	Н	"	"			-	В					
		"	70	В	"	В	"	"		- i	"	- i		"		В		В					
8 F	Repeat	subaroup 7	tests at T _C		and -55°C														l.				
	t _{PLH1}	3003	71	GND	GND				IN	OUT	GND						GND	GND	5.0 V	1C0 to 1Y	3	20	ns
Tc = 25°C	4 611	Fig. 4	72	"	GND			IN		"	"						5.0 V		"	1C1 to 1Y	"	"	
		,	73	"	5.0 V		IN			"	"						GND			1C2 to 1Y	"	"	
		"	74	"	5.0 V	IN				"	"						5.0 V	"	"	1C3 to 1Y		"	"
		"	75	"	GND							OUT	IN				GND			2C0 to 2Y		"	-
		"	76	=	GND						"	"		IN			5.0 V	-		2C1 to 2Y		"	-
		"	77	-	5.0 V						"	"			IN		GND			2C2 to 2Y		"	
L		"	78	"	5.0 V						"	"				IN	5.0 V		"	2C3 to 2Y		"	"
1	t _{PHL1}	"	79	"	GND				IN	OUT	"						GND	"	"	1C0 to 1Y		31	
			80	- "	GND			IN									5.0 V	-	- "	1C1 to 1Y		"	
			81	- :	5.0 V		IN			- "							GND			1C2 to 1Y		<u> </u>	
			82 83	-	5.0 V	IN						OUT	IN				5.0 V GND	-	-	1C3 to 1Y		-	
		"	84		GND GND							OUT "	IIN	IN			5.0 V			2C0 to 2Y 2C1 to 2Y	-	"	-
			85	"	5.0 V						"			IIN	IN		GND			2C2 to 2Y		"	
		"	86		5.0 V						"					IN	5.0 V			2C3 to 2Y		"	"
-	t _{PLH3}	"	87	IN	GND				5.0 V	OUT	"						GND			1G to 1Y		29	-
	. 2.10	"	88		"						"	OUT	5.0 V					IN		2G to 2Y		29	
1	t _{PHL3}	"	89	IN	"				5.0 V	OUT	"						"		"	1G to 1Y		37	
		"	90		"						"	OUT	5.0 V				"	IN	"	2G to 2Y		37	
f	t _{PLH5}	"	91	GND	5.0 V	GND	5.0 V			OUT	"				5.0 V	GND	IN	GND	"	A to 1Y		34	"
		"	92	=	5.0 V	GND	5.0 V				"	OUT			5.0 V	GND	IN	-	"	A to 2Y		"	"
		"	93	"	IN	5.0 V		GND		OUT	"			GND		5.0 V	5.0 V	"	"	B to 1Y	"	"	
L		"	94	"	IN	5.0 V		"			"	OUT		"		5.0 V	5.0 V		"	B to 2Y		"	
1	t _{PHL5}	"	95	"	GND				5.0 V	OUT	"	OI :T	5.0 V	"			IN	- "	-:-	A to 1Y		43	
			96		GND		CND			OUT	-	OUT			CND		IN	-	-	A to 2Y			
		"	97 98	"	IN IN		GND GND		"	OUT	"	OUT	"		GND GND	-	GND		-	B to 2Y	-	"	-
10 S			terminal co	11.11											GND	<u> </u>	GND		1	B to 2Y		l	
t	t _{PLH1} = t _{PLH5} =	3 to 30 ns 3 to 51 ns	s; t _{PHL1} = 3 s; t _{PHL5} = 3 ninal condit	to 47 ns to 65 ns	; t _{PLH3} = 3	3 to 44 ns	s; t _{PHL3} =	3 to 56 n	s;		virig iiiilik	.											

See footnotes at end of device type 02.

TABLE III. Group A inspection for device type 02 - Continued.

 $\underline{1}/$ Case X and 2 pins not referenced are NC. $\underline{2}/$ $I_{\rm IL}$ limits are as follows:

			Min/Ma	x limits (mA) fo	or circuits		
Test	Α	В	С	D	Е	F	G
I _{IL1}	Tests 17 and 28 001/15 tests 18 through 27 12/36	12/36	12/36	03/30	Tests 17 and 28 016/40 tests 18 and27 12/36 Tests 19 through 26 16/40	12/36	0/15

TABLE III. Group A inspection for device type 03. Terminal conditions (pins not designated may be high \geq 2.0 V; low \leq 0.7 V; or open).

			Cases	1	2	3	4	5	6 6	7	8	9	e nign ≥ 10	11	12	13	14	15	16				
		MIL-STD-	E, F				7		O	l '	O	3	10		12	13	1.4	13	10				I
Subgroup	Symbol	883 method	Cases <u>1</u> / 2, X	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20	Measured terminal	Lim	nits	Unit
			Test no.	S	1A	1B	1Y	2A	2B	2Y	GND	3Y	3B	3A	4Y	4B	4A	G	V _{cc}	1	Min	Max	ı
1	V _{OH}	3006	1	2.0 V		2.0 V	4 mA				GND	-						0.7 V	4.5 V	1Y	2.5		V
Tc = 25°C		"	2	"					2.0 V	4 mA	"									2Y			
		"	3	"							"	4 mA	2.0 V							3Y			-
		"	4	"							"				4 mA	2.0 V			"	4Y			
	V_{OL}	3007	5				4 mA				"							2.0 V		1Y		0.4	
		"	6							4 mA	"							"	"	2Y		"	
		"	7								"	4 mA							"	3Y		"	
		"	8								- "				4 mA					4Y			
	VIC		9	-18 mA							- "									S		-1.5	
			10		-18 mA															1A			
			11			-18 mA		40. 4			- "									1B			
			12					-18 mA	40. 4		- "									2A			
			13 14						-18 mA		-		40 ^						-	2B		-	
			14 15			-		 		-			-18 mA	-18 mA					-	3B 3A		-	-
			16								"			-10 IIIA		-18 mA				4B			
			17								"					-10 IIIA	-18 mA			4A			
			18								"						10 1117	-18 mA		G			
	I _{IL1}	3009	19	GND	0.4 V	5.5 V					"			1		1		GND	5.5 V	1A	2/	2/	mA
	·IL1	"	20	5.5 V	5.5 V	0.4 V					"							"	"	1B		=	"
		"	21	GND				0.4 V	5.5 V										"	2A		"	
		"	22	5.5 V				5.5 V	0.4 V		"								"	2B		"	"
		"	23	5.5 V							"		0.4 V	5.5 V					"	3B		"	"
		"	24	GND							"		5.5 V	0.4 V					"	3A		"	-
		"	25	5.5 V							"					0.4 V	5.5 V		"	4B		"	"
		"	26	GND							-					5.5 V	0.4 V		"	4A		"	-
	I_{IL2}		27	0.4 V							"							5.5 V	"	S		"	"
		"	28	5.5 V							"							0.4 V	"	G		"	
	I _{IH1}	3010	29	5.5 V	2.7 V						"								"	1A		20	μΑ
			30	GND		2.7 V					"								"	1B		"	
			31	5.5 V				2.7 V			- "									2A		"	
			32	GND					2.7 V				071/						- "	2B			
			33	GND									2.7 V	0.71/					- "	3B			
			34	5.5 V							-			2.7 V		271/				3A			
		"	35 36	GND 5.5 V												2.7 V	2.7 V		"	4B 4A			
}	I _{IH2}	3010	37	5.5 V	7.0 V												Z.1 V			1A		100	
	'IH2	"	38	GND	7.0 V	7.0 V					"								"	1B		"	-
		"	39	5.5 V		7.0 *		7.0 V											"	2A		"	
		"	40	GND				1.0.	7.0 V		"								"	2B		"	
		"	41	GND							"		7.0 V						"	3B		"	
		"	42	5.5 V							"			7.0 V					"	3A		"	
		"	43	GND							"					7.0 V			"	4B		"	
		"	44	5.5 V							"						7.0 V		"	4A		"	
	I _{IH3}	"	45	2.7 V							"							GND	"	S		40	"
		"	46 <u>3</u> /	GND														2.7 V		G		40	-
	I_{IH4}	"	47	7.0 V							"							GND	"	S		200	μΑ
		"	48 <u>3</u> /	GND							"							7.0 V		G		200	μΑ
	Ios	3011	49	"	5.5 V	5.5 V	GND											GND	"	1Y	-15	-100	mA
		"	50	"				5.5 V	5.5 V	GND	"								"	2Y		"	"
		"	51	"								GND	5.5 V	5.5 V						3Y		"	
			52	"							"		· ·		GND	5.5 V	5.5 V			4Y	"	"	-
	I _{CC1}	3005	53	5.5 V	5.5 V	5.5 V		5.5 V	5.5 V	L			5.5 V	5.5 V		5.5 V	5.5 V	5.5 V		V _{CC}		16	
			al conditions																				
3	Same to	ests, termina	al conditions	and limits	as subgro	oup 1, exce	$ept I_C = -5$	5°C and \	ıc tests oı	mitted.													

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See footnotes at end of device type 03.

TABLE III. <u>Group A inspection for device type 03</u> - Continued. Terminal conditions (pins not designated may be high \geq 2.0 V; low \leq 0.7 V; or open).

						16	erminai d	conditio	ns (pins	not des	signated	i may b	e high ≥	2.0 V; I	0.7	v; or op	en).						
		MIL-STD-	Cases E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16				
Subgroup	Symbol	883 method	Cases <u>1</u> / 2, X	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20	Measured terminal	Lim	iits	Unit
			Test no.	S	1A	1B	1Y	2A	2B	2Y	GND	3Y	3B	3A	4Y	4B	4A	G	V _{CC}		Min	Max	
7	Func-	3014	54	A	A	A	L	A	A	L	GND	L	A	A	Ĺ	A	A	A	5.0 V	All		max	
Tc = 25°C		"	55	В	A	A	"	Α	Α	"	"	-	Α	Α		Α	Α		"	outputs			
10 - 20 0	tests		56	"	В	В		В	В				В	В		В	В		"	outputo			
	10010	"	57	"	В	"	"	В	"	"	"		-	В		-	В	В			<u>4</u> /		
			58	"	A	"	Н	A	"	Н	"	Н		A	Н		A	-					
			59	"	A	Α	H	A	Α	H	"	Н.	Α	A	H	Α	A						
			60	"	B		- ''	В		- ii	"	- ''		В	L'		В	-					
			61	Α	В	"	H	В	"	Н	"	H		В	H		В						
			62		A		H	A		Н		H		A	H		A	-					
		,,	63		A	В	- ''	A	В	- ''	"	- ''	В	A	- ''	В	A						
8	Donoot	subgroup 7		- 112E°C					В				В		L L		_ ^		1				
9		3003	64	= +125°C :	and I _C = -:	JU-C	OUT				GND	1		1		1		GND	5.0 V	1A to 1Y	3	19	nc
9 Tc = 25°C	t _{PLH1}	Fig. 4	65	5.0 V	IIN	IN	OUT				"			-				UND "	3.U V	1B to 1Y	3	19	ns "
10 = 25°C		Fig. 4				IIN	001	IN		OUT									-				
			66	GND				IIN	INI	OUT									-	2A to 2Y			
			67	5.0 V					IN	OUT	- "	OUT	INI						-	2B to 2Y			-
			68	5.0 V								OUT	IN							3B to 3Y			
			69	GND								OUT		IN	OUT.				<u> </u>	3A to 3Y		الــــّــا	
			70	5.0 V											OUT	IN			-	4B to 4Y		⊢ :⊢	
			71	GND			OUT								OUT		IN		<u> </u>	4A to 4Y		الــــّــا	
	t _{PHL1}		72	GND	IN		OUT													1A to 1Y		اــــــــا	
			73	5.0 V		IN	OUT													1B to 1Y		⊢ :⊢	
			74	GND				IN		OUT										2A to 2Y		┷	
			75	5.0 V					IN	OUT										2B to 2Y		⊢ ∷⊢	
			76	5.0 V								OUT	IN	<u> </u>						3B to 3Y		⊢ :⊢	
			77	GND								OUT		IN	a					3A to 3Y		⊢ :⊢	
			78	5.0 V											OUT	IN				4B to 4Y		┷	
			79	GND		1 /									OUT		IN			4A to 4Y		<u> </u>	
	t _{PLH3}		80	5.0 V		5.0 V	OUT											IN		G to 1Y		25	
			81						5.0 V	OUT	"									G to 2Y			
			82	- "							"	OUT	5.0 V							G to 3Y		┷	
			83												OUT	5.0 V				G to 4Y		<u> </u>	
	t _{PHL3}	"	84	GND	5.0 V		OUT	5.01/		OUT								IN.	-	G to 1Y		26	
			85	-:-				5.0 V		OUT		OUT		501/						G to 2Y		-	
			86									OUT		5.0 V						G to 3Y		اــــــــا	
			87		5.01/	ONE	OUT								OUT		5.0 V	OND.		G to 4Y		- "	
	t _{PLH5}		88	IN	5.0 V	GND	OUT											GND		S to 1Y		28	
		"	89	- "				5.0 V	GND	OUT		OUT.	ONE	5.01/					- "	S to 2Y		╙┈┤	
			90	- "								OUT	GND	5.0 V						S to 3Y		الـــّـــا	
			91								- "				OUT	GND	5.0 V		- "	S to 4Y			
	t _{PHL5}		92	"	GND	5.0 V	OUT				"			ļ				IN	- "	S to 1Y	- "	32	"
			93	"				GND	5.0 V	OUT	"								"	S to 2Y			
			94	"							"	OUT	5.0 V	GND					"	S to 3Y	"		
		"	95	"							"			1	OUT	5.0 V	GND		. "	S to 4Y			- "
10	Same	tests and	terminal co	onditions	as for su	ubgroup 9	except)	$T_{\rm C} = +12$	<u>25°C a</u> nd	for follow	wing limit	s: t _{PLH1} a	and $t_{PHL_1} =$	3 to 29 r	ns; t _{PLH3} =	3 to 38 n	$s; t_{PHL3} =$	3 to 39 ns	s; t _{PLH5} =	3 to 42 ns; t _F	$_{HL5} = 3 \text{ to}$	ວ 48 ns.	
11	Same	tests, term	ninal condi	tions and	limits as	s for subo	aroup 10.	except 7	c = -55°	C													

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TABLE III. Group A inspection for device type 03 - Continued.

1/ Pins not designated are high \geq 2.0 V; low \leq 0.7 V; or open. Case X and 2 pins not referenced are NC.

2/ I_{IL} limits are as follows:

					Min/Max limits	s (mA) for circuit	s
Test	А	В	С	D	Е	F	G
I _{IL1}	135/370	016/40	20/44	03/30	0/20	12/36	0/15
I _{IL2}	270/740	12/36	40/88	06/60	0/10 for test 27 0/10 for test 28	24/72 except 12/36 test 28	0/15

 $\underline{3}\!/$ For circuit F, test 46 $\,$ I $_{\text{IH3}}$ limit is 20 $\mu\text{A}.$ For circuit F, test 48 $\,$ I $_{\text{IH3}}$ limit is 100 $\mu\text{A}.$

 $\underline{4}/$ Inputs: A ≥ 2.5 V minimum, B ≤ 0.4 V maximum. Outputs: H ≥ 1.5 V, L ≤ 1.5 V.

-							
Terminal conditions	(pins not	designated	may be	high > 1	2.() V	$low < 0.7 V \cdot or o$	nen).

						16	eminai (Jonallio	ns (pins	not des	ignated	may b	e high ≥	2.0 V; K	$JW \ge U.7$	v, or op	en).						
		MIL-STD-	Cases E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16				
Subgroup	Symbol	883 method	Cases <u>1</u> / 2, X	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20	Measured terminal	Lim	nits	Unit
			Test no.	S	1A	1B	1Y	2A	2B	2Y	GND	3Y	3B	3A	4Y	4B	4A	G	V _{CC}		Min	Max	
1	V _{OH}	3006	1		171		4 mA	271	- 20		GND	01	0.0	0/1		70	771	2.0 V	4.5 V	1Y	2.5	IVIGA	V
Tc = 25°C	*OH	"	2				110 (4 mA	"							2.0 0	T.0 V	2Y	2.0		
10 - 23 0			3							 111/-1	"	4 mA								3Y	-		
			4								"	111/-1			4 mA					4Y			
	V _{OL}	3007	5	2.0 V		2.0 V	4 mA				"				4111/5			0.7 V		1Y		0.4	
	V OL	3007	6	2.0 V		2.0 V	7111/1		2.0 V	4 mA	-							0.7 V		2Y		"	
			7	"					2.0 V	4111/1	"	4 mA	2.0 V							3Y		"	
			8	"							"	7 111/5	2.0 V		4 mA	2.0 V				4Y			
	VIC		9	-18 mA							-				7111/3	2.0 V				S		-1.5	
	VIC		10	-1011114	-18 mA						-									1A		-1.5	
			11		-10 IIIA	-18 mA					-									1B			
			12			-10 111/4		-18 mA			-									2A			
			13					-10 IIIA	-18 mA		"					1	1			2B			
			14						-10 IIIA		"		-18 mA			1	1			3B			
			15								-		- 10 IIIA	-18 mA		-				3B			
			16								-			-10 IIIA		-18 mA				3A 4B			
			17								-					-16 IIIA	-18 mA			4B 4A			
			18														-10 IIIA	-18 mA		G G		-	
		2000		CND	0.41/	E E V					-								E E \/		2/	2/	A
	I _{IL1}	3009	19	GND	0.4 V	5.5 V												GND	5.5 V	1A	<u> </u>	<u>2</u> /	mA "
			20	5.5 V	5.5 V	0.4 V		0.417	551/											1B			
			21	GND				0.4 V	5.5 V										- "	2A		- "	
			22	5.5 V				5.5 V	0.4 V				0.417					-		2B			
			23	5.5 V									0.4 V	5.5 V						3B			
			24	GND									5.5 V	0.4 V				-		3A			- :
			25	5.5 V												0.4 V	5.5 V			4B			
			26	GND												5.5 V	0.4 V			4A		- "	
	I_{IL2}	"	27	0.4 V														5.5 V	- "	S			- :
	—		28	5.5 V	071/													0.4 V	- "	G			
	I _{IH1}	3010	29	5.5 V	2.7 V															1A		20	μA
			30	GND		2.7 V													"	1B		"	
		"	31	5.5 V				2.7 V											"	2A		"	
		"	32	GND					2.7 V		"								"	2B		"	
		"	33	GND							"		2.7 V						"	3B		"	
		"	34	5.5 V							"			2.7 V					"	3A		"	
			35	GND							"					2.7 V			"	4B		"	
			36	5.5 V							"						2.7 V		"	4A		"	
	I _{IH2}	3010	37	5.5 V	7.0 V						"					ļ				1A		100	
		"	38	GND		7.0 V													"	1B		"	
		"	39	5.5 V				7.0 V			"								"	2A		"	
			40	GND					7.0 V		"		=							2B		"	
		"	41	GND									7.0 V							3B			- "
		"	42	5.5 V							"			7.0 V					"	3A		"	
		"	43	GND							"					7.0 V			"	4B		"	- "
		"	44	5.5 V							"						7.0 V		"	4A		"	"
	I _{IH3}		45	2.7 V														GND		S		40	
		"	46	GND							"					ļ		2.7 V		G		40	
	I _{IH4}		47	7.0 V							"							GND		S		200	μΑ
		"	48	GND							"							7.0 V	"	G		200	μΑ
	Ios	3011	49	"			GND				"							5.5 V	"	1Y	-15	-100	mA
		"	50	"						GND	"							-		2Y			
		"	51	"							"	GND						-	"	3Y		"	-
		"	52	"							"				GND			-	"	4Y		"	
	I _{CC1}	3005	53	5.5 V	5.5 V	5.5 V		5.5 V	5.5 V		"		5.5 V	5.5 V		5.5 V	5.5 V	-	"	V _{CC}		8.0	"
2			al conditions				ept T _C = +			omitted.													
							ept T _C = -5																

See footnotes at end of device type 04.

T ' 1 100' ('						١.
Larminal conditions (n	ine no	hatennisah t	may ha high	> 2 ハ ハ・	low < 0 / 0.00	וחנ
Terminal conditions (pi	1113 110	ı ucsiyilalcu	Illiay be iliqii	2.0 v,	$1000 \ge 0.7$ V, OI OPE	<i>i</i> 11/.
N						

							,,,,,,,,,,	001101110	(pc		ngnatoo	i iliay b	<u> </u>	<u></u> , , ,	7VV <u></u> 0.7	v, o. op	0						
		MIL-STD-	Cases E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16				I
Subgroup	Symbol		Cases 1/	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20	Measured	Lin	nits	Unit
		method	2, X																	terminal			I
			Test no.	S	1A	1B	1Y	2A	2B	2Y	GND	3Y	3B	3A	4Y	4B	4A	G	V_{CC}		Min	Max	
7	Func-	3014	54	Α	Α	Α	Н	Α	Α	Н	GND	Н	Α	Α	Η	Α	Α	Α	5.0 V	All			
$Tc = 25^{\circ}C$		"	55	В	Α	Α	"	Α	Α	"	"		Α	Α	"	Α	Α	"	"	outputs			
	tests		56		В	В	"	В	В	"	"		В	В	"	В	В	"	"				
		"	57	"	В	"	"	В		"	"			В		"	В	В	"		<u>3</u> /		
		"	58	"	Α	"	L	Α	"	L	"	L		Α	L	"	Α		"				
		"	59	"	Α	Α	L	Α	Α	L	"	L	Α	Α	L	Α	Α		"				
		"	60	"	В	"	Н	В	"	Н	"	Н		В	Н		В		"				
		"	61	Α	В	"	L	В	-	L	"	L		В	L		В						
		"	62	"	Α	"	L	Α	"	L	"	L		Α	L		Α						
		"	63	"	Α	В	Н	Α	В	Н	"	Н	В	Α	Н	В	Α						
	Repeat	subgroup 7	tests at T _C		and $T_C = -$	55°C																	
9	t _{PLH1}	3003	64	GND	IN		OUT				GND							GND	5.0 V	1A to 1Y	3	17	ns
Tc = 25°C		Fig. 4	65	5.0 V		IN	OUT				"							"	"	1B to 1Y	"	"	-
		"	66	GND				IN		OUT	"									2A to 2Y			-
		"	67	5.0 V					IN	OUT	"									2B to 2Y			-
		"	68	5.0 V							"	OUT	IN							3B to 3Y			-
		"	69	GND							"	OUT		IN					"	3A to 3Y			-
		"	70	5.0 V							"				OUT	IN			"	4B to 4Y			
		"	71	GND							"				OUT		IN			4A to 4Y			
	t _{PHL1}	"	72	GND	IN		OUT				"									1A to 1Y			
		"	73	5.0 V		IN	OUT				"							"		1B to 1Y	"		
		"	74	GND				IN		OUT	"							-	-	2A to 2Y	"		-
		"	75	5.0 V					IN	OUT	"									2B to 2Y			
		"	76	5.0 V							"	OUT	IN							3B to 3Y	"	"	
		"	77	GND							"	OUT		IN						3A to 3Y	"	"	
		"	78	5.0 V							"				OUT	IN				4B to 4Y		"	
		"	79	GND							"				OUT		IN		-	4A to 4Y	"		-
	t _{PLH3}	"	80	GND	5.0 V		OUT				"							IN		G to 1Y	"	22	
		"	81	"				5.0 V		OUT	"									G to 2Y	"	"	
		"	82	"							"	OUT		5.0 V						G to 3Y	"	"	
		"	83	=							"				OUT		5.0 V		"	G to 4Y	"	"	
	t _{PHL3}	"	84	5.0 V		5.0 V	OUT				"								-	G to 1Y	"	23	-
		"	85	"					5.0 V	OUT	"									G to 2Y	"	"	
		"	86	=							"	OUT	5.0 V						"	G to 3Y	"	"	
		"	87	"							"				OUT	5.0 V		"	"	G to 4Y	"	"	"
	t _{PLH5}	"	88	IN	5.0 V	GND	OUT				"							GND	"	S to 1Y	"	25	"
		"	89	"				5.0 V	GND	OUT	"							"	"	S to 2Y	"	"	"
		"	90	"							"	OUT	GND	5.0 V				"	"	S to 3Y	"		
		"	91	=							"				OUT	GND	5.0 V	-	"	S to 4Y	"	"	
	t _{PHL5}	"	92	"	GND	5.0 V	OUT				"							"	"	S to 1Y	"	29	"
		"	93	"				GND	5.0 V	OUT	"							"	"	S to 2Y	"	"	
		"	94	"							"	OUT	5.0 V	GND				"	"	S to 3Y	"		"
		"	95	"							"				OUT	5.0 V	GND	"	"	S to 4Y	"	"	
10	Same t	ests and ter	minal condit	ions as for	subgroup	9, except	$T_C = +125$	C and for	following	limits: t _{PLH}	1 and tehl1	= 3 to 26	ns; t _{PLH3} =	3 to 33 ns	$t_{PHL3} = 3 tc$	35 ns; t _{PL}	$_{H5} = 3 \text{ to } 38$	3 ns; t _{PHL5} =	3 to 44 ns	S			
11	Same t	ests, termina	al conditions	and limits	as for sub	ogroup 10,	except To	= -55°C															

 $[\]underline{1/}$ Case X and 2 pins not referenced are NC. $\underline{2/}$ $I_{\rm IL}$ limits are as follows:

					Min/Max limits (m	F G12/36 0/1524/72 except 0/15							
Test	Α	В	С	D	Е	F	G						
I _{IL1}	135/370	016/40	20/44	03/30	0/20	12/36	0/15						
I _{IL2}	270/740	12/36	40/88	06/60	0/10 for test 27	24/72 except	0/15						
					0/10 for test 28	12/36 test 28							

TABLE III. Group A inspection for device type 05.

Terminal conditions (pins not designated may be high $\ge 2.0 \text{ V}$: low $\le 0.7 \text{ V}$; or open).

						Te	erminal (conditio	ns (pins	not des	signated	l may b	e high ≥	2.0 V; k	$0.7 \le 0.7$	V; or op	en).						
		MIL-STD-	Cases E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16				
Subgroup	Symbol	883 method	Cases <u>1</u> / 2, X	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20	Measured terminal	Lin	nits	Unit
			Test no.	D3	D2	D1	D0	Υ	W	S	GND	С	В	Α	D7	D6	D5	D4	Vcc	1	Min	Max	
1	V _{OH}	3006	1					-1 mA		0.7 V	GND	2.0 V	2.0 V	2.0 V	2.0 V				4.5 V	Υ	2.4		V
Tc = 25°C	-	"	2				0.7 V		-1 mA	"	"	0.7 V	0.7 V	0.7 V						W	2.4		
	V _{OL}	3007	3				0.7 V	4 mA		"	"	0.7 V	0.7 V	0.7 V						Y		0.4	"
		"	4						4 mA	"	"	2.0 V	2.0 V	2.0 V	2.0 V				"	W		0.4	"
	V _{IC}		5	-18 mA							"									D3		-1.5	-
			6		-18 mA						"									D2			
			7			-18 mA					"									D1			
			8				-18 mA				"									D0		"	"
			9							-18 mA	- "								- "	S		-	-
			10									-18 mA								C			
			11								<u> </u>		-18 mA	10 1					<u> </u>	В		<u> </u>	
			12											-18 mA	40 4					A D7		-	
			13 14												-18 mA	40 4				D7			
			15								-					-18 mA	-18 mA		-	D6 D5		-	-
			16				1										-10 IIIA	-18 mA		D3			
	I _{IL1}	3009	17	0.4 V	5.5 V	5.5 V	5.5 V			GND	"	GND	5.5 V	5.5 V	5.5 V	5.5 V	5.5 V	5.5 V	5.5 V	D3	2/	2/	mA
	'IL1	"	18	5.5 V	0.4 V	5.5 V	3.5 V			UIVD "		UIVD "	5.5 V	GND	3.5 V	0.5 V	0.5 V	3.5 V	3.5 V	D2	<u> 2/</u>	"	"
		"	19	"	5.5 V	0.4 V							GND	5.5 V					"	D1		"	"
		"	20	"	U.U V	5.5 V	0.4 V						GND	GND					"	D0		"	"
		"	21	"	"	"	5.5 V			"	"	5.5 V	5.5 V	5.5 V	0.4 V				"	D7		"	"
		"	22	"	"	"	"			"	"	"	5.5 V	GND	5.5 V	0.4 V			"	D6		"	"
		"	23	"	"	"	"			"	"		GND	5.5 V		5.5 V	0.4 V		"	D5		"	"
		"	24	"	"	"	"			"	"		GND	GND		5.5 V	5.5 V	0.4 V	"	D4		"	"
	I _{IL2}	"	25							0.4 V	"									S			
	I _{IL3}	"	26								"	0.4 V								С			
		"	27								"		0.4 V							В	-		-
		"	28								"			0.4 V					"	Α		"	"
	I _{IH1}	3010	29	2.7 V	GND	GND	GND			GND	"	5.5 V	GND	GND	GND	GND	GND	GND	"	D3		20	μΑ
		"	30	GND	2.7 V	GND	"			"	"	"	GND	5.5 V		"	"	"	"	D2		"	"
		"	31	"	GND	2.7 V	"			"	"	"	5.5 V	GND				"	"	D1		"	
			32	"	GND	GND	2.7 V			"			5.5 V	5.5 V				"	"	D0		"	"
			33							2.7 V	"									S			
			34			<u> </u>					<u> </u>	2.7 V	0.7.1/						<u> </u>	С		<u> </u>	-
			35		1	!	 			-		1	2.7 V	271/		-			-	В	-	-	
			36 37	GND	GND	GND	GND			GND	- "	GND	GND	2.7 V GND	2.7 V	GND	GND	GND	-	A D7		-	
1			38	שואט "	GND "	UND "	UND "	-	 	UND "	-	שואט "	GND	5.5 V	GND	2.7 V	GND	UND "	-	D7	 	-	
		"	39	"		"	"			"			5.5 V	GND	GIND "	GND	2.7 V		"	D5		"	
			40	"	"	"	"			"	"		5.5 V	5.5 V		GND	GND	2.7 V	"	D5	 	"	
	I _{IH2}	"	41	7.0 V	"	"	"			"	"	5.5 V	GND	GND		U U	"	GND	"	D3		100	"
	'IH2	"	42	GND	7.0 V	GND				"	"	J.J V	GND	5.5 V				UIVD "		D2		"	
			43	"	GND	7.0 V							5.5 V	GND					"	D1		"	"
1		"	44	"	GND	GND	7.0 V						5.5 V	5.5 V					"	D0		"	"
		"	45		0	05	1			7.0 V	"		0.0 .	0.0 .						S			
1		"	46								"	7.0 V								C			
1		"	47		1						"		7.0 V							В			
		"	48								"			7.0 V						A			
		"	49	GND	GND	GND	GND			GND	"	GND	GND	GND	7.0 V	GND	GND	GND		D7			
		"	50	"	"	"	"			"	"	"	GND	5.5 V	GND	7.0 V	GND	"	"	D6		"	"
		"	51	"	"	"	"			"	"		5.5 V	GND	"	GND	7.0 V	"	"	D5		"	
		"	52	"	"	"	"			"	"		5.5 V	5.5 V			GND	7.0 V	"	D4		"	"

See footnotes at end of device type 05.

TABLE III. Group A inspection for device type 05 - Continued.

						Te	erminal o	condition	ns (pins	not des	signated	l may b	e high ≥	2.0 V; lo	$w \le 0.7$	V; or op	en).						
		MIL-STD-	Cases E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16				
Subgroup	Symbol	883 method	Cases <u>1</u> / 2, X	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20	Measured terminal	Lim	nits	Unit
			Test no.	D3	D2	D1	D0	Υ	W	S	GND	С	В	Α	D7	D6	D5	D4	Vcc		Min	Max	
1	I _{OZH}		53	5.5 V	5.5 V	5.5 V	5.5 V	2.7 V		2.0 V	GND	5.5 V	5.5 V	5.5 V	0.7 V	5.5 V	5.5 V	5.5 V	5.5 V	Y		20	μΑ
Tc = 25°C			54	=	"	"	"		2.7 V	=	"		"	"	2.0 V		"	-		W		20	-
	I _{OZL}		55			"	"	0.4 V			"		"	"	2.0 V					Υ		-20	
			56	"	"	"	"		0.4 V	"	"			"	0.7 V	"	"			W		-20	
	los	3011	57				GND	GND	GND	GND	- "	gnd	GND	gnd	5.5 V	ļ				Y W	-30	-130	mA "
	3/ I _{CC1}	3011 3005	58 59	5.5 V	5.5 V	5.5 V	5.5 V		GND		"	5.5 V	5.5 V	5.5 V	5.5 V	5.5 V	5.5 V	5.5 V		V _{CC}	-30	-130 10	
	I _{CC2}	3006	60	5.5 V	5.5 V	5.5 V	5.5 V			5.5 V		5.5 V	5.5 V	5.5 V	5.5 V	5.5 V	5.5 V	5.5 V	"	V _{CC}		12	
2		ests, termina						125°C and	V _{LC} tests		I	0.0 1	0.0 1	0.0 1	0.0 1	0.0 1	0.0 1	0.0 1	l	• (()	I		
3		ests, termina																					
7	Func-	3014	61	В	В	В	Ä	Н	L	В	GND	В	В	В	В	В	В	В	5.0 V	Y, W			
Tc = 25°C	tional	"	62	Α	Α	Α	Α	Н	L	"	"		"	"	Α	Α	Α	Α	"	"			
	tests	"	63	-	-		В	L	Н	-			"	"	-		"	-	"	"			
		"	64	-	"	"	"	Н	L		"		"	Α	-		"		"	"			
			65			В		L	H					A									
			66			- :	- :	H	L	- "	- "		<u>A</u>	В		-:-		- :					
			67 68	,	B "	"	"	H	H L	,	"		-	B A						"		<u>4</u> /	
		"	69	В	"	"	"	- ''	Н	"	"			A						"		4/	
		"	70	"	"	"	"	Н		"	"	Α	В	В						"			
		"	71	"	"	"	"	Ĺ	H	"	"	"	-	В			"	В		"			
		"	72	"	"	"	"	Н	L	"	"	"	"	Α	"	"	"	"	"	"			
		"	73	"	"	"	"	L	Н	"	"	"	"	Α		"	В	"	"	"			
		"	74			"	"	Н	L		"		Α	В			"			"			
			75	"	"	"	"	L	Н	"	"	"		В		В			"	"			
		. "	76	-:-	- :	- :	- :	H	L	"	- "	-		A		<u> </u>			<u> </u>				
8	Panaat	subgroup 7	77	1125°C	and To -	EE°C		L	Н				-	Α	В								
9	t _{PLH1}	3003	78	= +125-0	and ic = -	55°C.	IN	OUT		GND	GND	GND	GND	GND		1			5.0 V	D0 to Y	3	33	ns
Tc = 25°C	PLH1	(Fig. 4)	79			IN	1111	"		UND "	UND "	UND "	GND	5.0 V					3.0 V	D1 to Y	"	"	"
.0 - 20 0		(1.13.1)	80		IN			"		"	"		5.0 V	GND						D2 to Y		"	
		"	81	IN				"		"	"		5.0 V	5.0 V					"	D3 to Y	"	"	"
		"	82					"		"	"	5.0 V	GND	GND				IN	"	D4 to Y	"	"	"
		"	83					"		"	"	-	GND	5.0 V			IN		"	D5 to Y	-		
			84					"		"	"	"	5.0 V	GND		IN			"	D6 to Y	"	"	
	_	"	85				IN	- "		- "	"	GND	5.0 V GND	5.0 V	IN	ļ				D7 to Y			-
	t _{PHL1}		86 87			IN	IIN	"		"	"	GND "	GND	GND 5.0 V						D0 to Y D1 to Y			
			88		IN	IIN		"		"	"		5.0 V	GND						D1 to 1		"	
		"	89	IN	111			"		"	"		5.0 V	5.0 V						D3 to Y			
		"	90					"		"	"	5.0 V	GND	GND				IN		D4 to Y	"	"	
		"	91					"		"	"	"	GND	5.0 V			IN		"	D5 to Y	"	"	"
		"	92					"		"	"	"	5.0 V	GND		IN			"	D6 to Y	"	"	"
		"	93					"		"	"	"	5.0 V	5.0 V	IN				"	D7 to Y	"	"	"
	t _{PLH2}	. "	94				IN		OUT	- "	- "	GND	GND	GND					- "	D0 to W	- "	20	-
			95		IN	IN				- "	- "	-	GND	5.0 V		-			-	D1 to W	-		-
			96 97	IN	IIN				"	,	"		5.0 V 5.0 V	GND 5.0 V		-				D2 to W D3 to W			
		"	98	IIN					"	"	"	5.0 V	GND	GND				IN	"	D3 to W		"	"
		"	99						"	"	"	3.0 v	GND	5.0 V			IN			D5 to W		"	
		"	100						"	"	"	"	5.0 V	GND		IN			"	D6 to W	"	"	
		"	101						"	"	"	"	5.0 V	5.0 V	IN				"	D7 to W	"	"	"

See footnotes at end of device type 05.

		MIL-STD-	Cases E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16				
Subgroup	Symbol	883 method	Cases <u>1</u> / 2, X	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20	Measured terminal	Lim	nits	Unit
			Test no.	D3	D2	D1	D0	Υ	W	S	GND	С	В	Α	D7	D6	D5	D4	V _{cc}		Min	Max	ł
9	t _{PHL2}	3003	102				IN		OUT	GND	GND	GND	GND	GND					5.0 V	D0 to W	3	20	ns
Tc = 25°C		(Fig. 4)	103			IN			"	"	"	"	GND	5.0 V						D1 to W			"
		"	104		IN					"	"		5.0 V	GND					-	D2 to W			-
		"	105	IN					"	"	"	"	5.0 V	5.0 V						D3 to W			
		"	106							"	"	5.0 V	GND	GND				IN		D4 to W	-	-	"
		"	107						"	"	"	"	GND	5.0 V			IN			D5 to W	"		"
		"	108						"	"	"	"	5.0 V	GND		IN				D6 to W	"	"	"
		"	109						"	"	"	"	5.0 V	5.0 V	IN				"	D7 to W	"		"
	t _{PLH5}	"	110			5.0 V	GND	OUT		"	"	GND	GND	IN					"	A to Y	"	50	"
		"	111		5.0 V		"	"		"	"	GND	IN	GND					"	B to Y	"		"
		"	112				"	"		"	"	IN	GND	GND				5.0 V	"	C to Y	"		"
	t _{PHL5}	"	113			5.0 V	"	"		"	"	GND	GND	IN						A to Y	"	"	"
		"	114		5.0 V		"	"		"	"	GND	IN	GND						B to Y	"	"	"
		"	115				"	"		"	"	IN	GND	GND				5.0 V		C to Y	"	"	"
	t _{PLH6}	"	116			5.0 V	"		OUT	"	"	GND	GND	IN						A to W	"	38	"
		"	117		5.0 V		"		"	"	"	GND	IN	GND					"	B to W	"		"

IN

GND

GND

IN

GND

IN

IN

GND

GND

IN

GND

GND

GND

5.0 V

5.0 V

C to W

A to W

B to W

C to W

S to Y

S to W

50

32

45

45

50

60

35

35

5.0 V

GND

GND

5.0 V

5.0 V

GND

GND

OUT

OUT

OUT

1/ Case X and 2 pins not referenced are NC.

118

119

120

121

122

123

124

125

126

127

128

5.0 V

2/ I_{IL} limits are as follows:

t_{PZH1}

t_{PZH2}

			Min/Max li	mits (mA) for cir	cuits		
Test	Α	В	С	D	Е	F	G
I _{IL1}	16/40	012/36	16/40	03/30	005/72	105/345	0/15
I _{IL2}	0/20	12/36	12/36	03/30	002/150	16/40	0/15
I _{IL3}	12/36	12/36	12/36	03/30	10/34	16/40	0/15

 $3/I_{OS}$ limits for circuits A, B, D, F, and G are -15 to -100 mA.

 $\underline{4}/$ Inputs: A \geq 2.5 V minimum, B \leq 0.4 V maximum. Outputs: H \geq 1.5 V, L \leq 1.5 V.

TABLE III. Group A inspection for device type 06. Terminal conditions (pins not designated may be high \geq 2.0 V; low \leq 0.7 V; or open).

													e nign ≥										
		MIL-STD-	Cases E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16				
Subgroup	Symbol	883 method	Cases <u>1</u> / 2, X	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20	Measured terminal	Lim	nits	Unit
			Test no.	S	1A	1B	1Y	2A	2B	2Y	GND	3Y	3B	3A	4Y	4B	4A	G	V _{CC}		Min	Max	
	1/	2000		0.7 V	2.0 V	ID		ZA	ZD	21		31	30	SA	41	4D	4A	0.7 V	4.5 V	1Y	2.4	IVIAX	V
1	V _{OH}	3006	1	U.7 V	2.0 V		-1 mA	0.01/		4 4	GND "							0.7 V	4.5 V		2.4		V
Tc = 25°C		,	2	"				2.0 V		-1 mA				0.01/						2Y			
			3	"								-1 mA		2.0 V						3Y			
			4												-1 mA		2.0 V			4Y			-
	V _{OL}	3007	5	2.0 V		0.7 V	12 mA													1Y		0.4	
		"	6	"					0.7 V	12 mA	"									2Y			
		"	7	"							"	12 mA	0.7 V							3Y			
		"	8	"							"				12 mA	0.7 V			"	4Y		"	
	VIC		9	-18 mA							"								"	S		-1.5	"
			10		-18 mA						"									1A			-
			11			-18 mA					"									1B			
			12					-18 mA			"									2A		"	
			13						-18 mA		"									2B		"	
			14								"		-18 mA							3B		"	
			15								"			-18 mA						3A			
			16								"					-18 mA			"	4B		"	
			17								"						-18 mA		"	4A		"	
			18								"							-18 mA	"	G		"	"
	I _{IL1}	3009	19	GND	0.4 V						"								5.5 V	1A	2/	2/	mA
	101	"	20	5.5 V		0.4 V					"								"	1B	-	-	
			21	GND		0		0.4 V			"									2A			
			22	5.5 V				0.4 1	0.4 V										"	2B			
			23	5.5 V					0.7 1		"		0.4 V						"	3B			
			24	GND							"		0. 4 V	0.4 V						3A			
			25	5.5 V										U.4 V		0.4 V				4B			
			26	GND							"					0.4 V	0.4 V			4A			
	-	,,	27	GIND													U.4 V	0.4 V		G			
	I _{IL2}		28	0.4 V														0.4 V		S			
	_	3010	29	5.5 V	2.7 V						-									1A		20	
	I _{IH1}	3010			Z.1 V	0.71/																20	μA "
			30	GND		2.7 V		0.71/												1B			
			31	5.5 V				2.7 V	071/		"									2A			
			32	GND					2.7 V		"								- "	2B			
			33	GND									2.7 V	071/						3B			-
			34	5.5 V										2.7 V						3A			
			35	GND												2.7 V				4B			
			36	5.5 V													2.7 V	0.71/		4A		- "	-
			37															2.7 V		G			
	I _{IH2}	3010	38	5.5 V	7.0 V														- "	1A		100	
			39	GND		7.0 V					"								"	1B		"	
			40	5.5 V				7.0 V			-								"	2A		"	
			41	GND					7.0 V		"								"	2B		"	
1		"	42	GND							"		7.0 V						"	3B		"	"
		"	43	5.5 V							"			7.0 V					"	3A		"	
		"	44	GND							"					7.0 V			"	4B		"	"
		"	45	5.5 V							"						7.0 V		"	4A		"	"
		"	46								"							7.0 V		G		"	
	I _{IH3}	"	47	2.7 V							"								"	S		40	"
	I _{IH4}	"	48	7.0 V							"									S		200	
	I _{OZH}		49	2.0 V	0.7 V		2.7 V				"							2.0 V	"	1Y		20	-
1			50	"				0.7 V		2.7 V	"							"	"	2Y		"	"
1			51	"							"	2.7 V		0.7 V				-	"	3Y		"	"
			52	"							"				2.7 V		0.7 V	"	"	4Y		"	
	I _{OZL}		53	0.7 V		2.0 V	0.4 V				"							"	"	1Y		-20	
1	OZL		54	"			-		2.0 V	0.4 V	"									2Y		"	
			55	"							"	0.4 V	2.0 V							3Y		"	
1			56	"							"				0.4 V	2.0 V			"	4Y		"	
			00	l	1	l	l	1	l		l	ı		1	U.→ V	2.0 V			1	71	1		

See footnotes at end of device type 06.

TABLE III. <u>Group A inspection for device type 06</u> - Continued.

Terminal conditions (pins not designated may be high > 2.0 V; low < 0.7 V; or open).

						Τe	erminal	conditio	ns (pins	not des	signated	l may b	e high ≥	2.0 V; ld	$w \le 0.7$	V; or op	en).						
		MIL-STD-	Cases E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16				
Subgroup	Symbol	883 method	Cases <u>1</u> / 2, X	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20	Measured terminal	Lin	nits	Unit
			Test no.	S	1A	1B	1Y	2A	2B	2Y	GND	3Y	3B	3A	4Y	4B	4A	G	V _{cc}		Min	Max	
	Ios	3011	57	GND	5.5 V		GND											GND	"	1Y	-30	-130	mA
	<u>3</u> /	"	58	"				5.5 V		GND	"								"	2Y	"	"	
		"	59	"							"	GND		5.5 V					"	3Y		"	
			60	"	551/	5.5.7		5.51/	5.51/		- :-			5.5.1	GND	5.5.7	5.5 V		- "	4Y	- "		- :
	I _{CC1}	3005	61		5.5 V GND	5.5 V		5.5 V	5.5 V		- "		5.5 V GND	5.5 V GND		5.5 V GND	5.5 V	-		V _{CC}		12	-
	I _{CC2}	"	62 63		GND	GND		GND GND	GND GND		"		GND	GND		GND	GND GND	5.5 V	"	V _{CC}		18 19	
2		oete tormin	al conditions	and limite			ont T +			omittod		l	GND	GND		GND	GND	3.5 V		VCC	l	19	
3			al conditions																				
7	Func-	3014	64	В	B	B B	I	B	В	I I	GND		В	В		В	В	В	5.0 V	All			
Tc = 25°C		"	65	"	В	A	Ĺ	В	A	Ĺ	"	Ĺ	A	В	Ē	A	В	-	"	outputs			
	tests		66		Α		Н	Α		Н		Н	"	Α	Н		Α		"				
		"	67	"	В	"	L	В	"	L	"	L	"	В	L		В		"		4/		
		"	68	Α	В	"	Н	В	"	Н	"	Н	"	В	Н		В		"		-		
		"	69	"	Α	"	Н	Α	"	Н	"	Н	"	Α	Н	"	Α		"				
		"	70		Α	В	L	Α	В	L	"	L	В	Α	L	В	Α		"				
		"	71	"	В	В	L	В	В	L	"	L	В	В	L	В	В		"				
8	Repeat		tests at T _C			.55°C																	
9	t _{PLH1}	3003	72	GND	IN		OUT				GND							GND	5.0 V	1A to 1Y	3	23	ns
$Tc = 25^{\circ}C$		Fig. 4	73	5.0 V		IN	OUT				-:									1B to 1Y			-:-
			74	GND				IN		OUT								-	-:-	2A to 2Y	-:-		
		,,	75 76	5.0 V 5.0 V		-			IN	OUT	-	OUT	IN	-				-	-	2B to 2Y 3B to 3Y	-		-
			77	GND								OUT	IIN	IN						3A to 3Y			
		"	78	5.0 V							"	001		IIN	OUT	IN			"	4B to 4Y			
		"	79	GND							"				OUT	111	IN			4A to 4Y			
	t _{PHL1}	"	80	GND	IN		OUT				"				001				"	1A to 1Y			
	11121	"	81	5.0 V		IN	OUT				"								"	1B to 1Y		"	
		"	82	GND				IN		OUT	"								"	2A to 2Y			
		"	83	5.0 V					IN	OUT	"								"	2B to 2Y		"	-
		"	84	5.0 V							"	OUT	IN					-	"	3B to 3Y	-	"	-
		"	85	GND							"	OUT		IN					"	3A to 3Y	"	"	
		"	86	5.0 V	ļ						- "	ļ			OUT	IN			- "	4B to 4Y		- "	
			87	GND	CND	F 0 \	OUT					ļ			OUT		IN			4A to 4Y	-		-
	t _{PLH5}	,,	88 89	IN "	GND	5.0 V	OUT	GND	5.0 V	OUT	- "	1		1				-	-	S to 1Y S to 2Y	-	26	
		"	90	"				טאט	5.0 V	001	"	OUT	5.0 V	GND					"	S to 3Y			
		"	91	"	<u> </u>	 	<u> </u>				"	001	J.U V	CIAD	OUT	5.0 V	GND		-	S to 4Y			
	t _{PHL5}	"	92	"	5.0 V	GND	OUT				"	1			001	0.0 7	0.10		"	S to 1Y			
	-FRLD	"	93	"		1		5.0 V	GND	OUT	"								"	S to 2Y	"		"
		"	94	"							"	OUT	GND	5.0 V					"	S to 3Y		"	
		"	95	"							"				OUT	GND	5.0 V	"	"	S to 4Y		"	
	t _{PZH3}	"	96	GND	5.0 V		OUT				"							IN	"	G to 1Y	"	35	"
		"	97					5.0 V		OUT	"								"	G to 2Y			
		"	98	"							"	OUT		5.0 V					"	G to 3Y			-
		"	99	"							"				OUT		5.0 V			G to 4Y	"	"	
	t _{PZL3}	. "	100	5.0 V	ļ	GND	OUT				- "	ļ						- "	- "	G to 1Y	- "		
		"	101	- "		ļ			GND	OUT	"	OUT	OND	<u> </u>						G to 2Y			
			102	- "							- "	OUT	GND		OUT	CND				G to 3Y	-	-	-
	1	L	103		<u> </u>	·	<u> </u>		L	<u> </u>			L	J	001	GND				G to 4Y	l		_

See footnotes at end of device type 06.

TABLE III. Group A inspection for device type 06 - Continued.

Terminal conditions (pins not designated may be high $\geq 2.0 \text{ V}$: low $\leq 0.7 \text{ V}$: or open).

							,,,,,,,,,,,		- (1 -		9		- 3	- ,			- /						
		MIL-STD-	Cases E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16				
Subgroup	Symbol	883 method	Cases <u>1</u> / 2, X	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20	Measured terminal	Lim	nits	Unit
			Test no.	S	1A	1B	1Y	2A	2B	2Y	GND	3Y	3B	3A	4Y	4B	4A	G	V _{CC}		Min	Max	
9	t _{PHZ3}	3003	104	5.0 V		5.0 V	OUT				GND							IN	-	G to 1Y	3	35	ns
$Tc = 25^{\circ}C$		Fig. 5	105	"					5.0 V	OUT										G to 2Y		"	
			106	"							"	OUT	5.0 V						"	G to 3Y		"	"
			107	"							"				OUT	5.0 V			"	G to 4Y		"	"
	t _{PLZ3}	"	108	GND	GND		OUT				"									G to 1Y		30	
			109	"				GND		OUT	"								"	G to 2Y		"	
			110	"							"	OUT		GND					"	G to 3Y		"	"
1		"	111	"				ĺ	ĺ	ĺ	"				OUT	ĺ	GND		"	G to 4Y	"	"	

Same tests, terminal conditions and limits as subgroup 9, except T_C = +125°C and for the following: t_{PLH1} and t_{PHL1} = 3 to 35 ns; t_{PLH5} and t_{PHL5} = 3 to 39 ns; t_{PZH3}, t_{PZL3}, and t_{PHZ3} = 3 to 53 ns; t_{PLZ3} = 3 to 45 ns.

- 1/ Case X and 2 pins not referenced are NC.
- $2/I_{IL}$ limits shall be as follows:

			Min/Max lin	nits (mA) for circ	cuits		
Test	Α	В	С	D	Е	F	G
I _{IL1}	15/38	16/40	20/44	0/30	0/20	12/36	0/15
I _{IL2} test 27	0/20	16/40	20/44	0/30	0/10	12/36	0/15
I _{IL2} test 28	0/20	32/80	40/88	0/60	0/10	24/72	0/15

- $3/I_{OS}$ limits for circuits B, C, D, F, and G are -15 to -100 mA.
- $\underline{4}/$ Inputs: A \geq 2.5 V minimum, B \leq 0.4 V maximum.

Outputs: Output voltages shall be either:

- a. H = 2.5 volts minimum and L = 0.4 volt maximum when using a high speed checker double comparator, or
- b. $H \ge 1.5$ volts and $L \le 1.5$ volts when using a high speed checker single comparator.
- c. Attributes data only is required for subgroups 7 and 8.

T_{PLH1} and T_{PHL1} = 3 to 35 nS; T_{PLH5} and T_{PHL5} = 3 to 39 nS; T_{PZH3}, T_{PZL3}, and T_{PHZ3} = 3 to 53 nS; T_{PLZ3} = 3 to 45 nS
 Same tests, terminal conditions and limits as subgroup 10, except T_C = -55°C.

TABLE III. Group A inspection for device type 07. Terminal conditions (pins not designated may be high \geq 2.0 V; low \leq 0.7 V; or open).

						16	eminai	conditio		not des	signated		e high ≥										
		MIL-STD-	Cases E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16				
Subgroup	Symbol	l 883 method	Cases <u>1</u> / 2, X	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20	Measured terminal	Lim	iits	Unit
			Test no.	S	1A	1B	1Y	2A	2B	2Y	GND	3Y	3B	3A	4Y	4B	4A	G	V _{cc}		Min	Max	
1	V	3006	1	0.7 V	0.7 V	ID	-1 mA	2/1	20	- 21	GND	31	30	3/1	41	40	4//	0.7 V	4.5 V	1Y	2.4	IVIAA	V
	V _{OH}	3006		U.7 V	U.7 V		-I IIIA	0.71/		1 Λ	GIND "							U.7 V	4.5 V		2.4		
Tc = 25°C		"	2	"				0.7 V		-1 mA				0.71/						2Y			
			3									-1 mA		0.7 V						3Y			
			4												-1 mA		0.7 V			4Y			
	V _{OL}	3007	5	2.0 V		2.0 V	12 mA													1Y		0.4	
		. "	6	"					2.0 V	12 mA	"									2Y			
		"	7	"							"	12 mA	2.0 V							3Y			
		"	8	"							"				12 mA	2.0 V			"	4Y			"
	VIC		9	-18 mA							"								"	S		-1.5	
			10		-18 mA						-									1A		"	
			11			-18 mA					"									1B			
			12					-18 mA			"									2A			
			13						-18 mA		"									2B			
			14								"		-18 mA							3B			
			15								"			-18 mA						3A			
			16								"					-18 mA			"	4B			
			17								"						-18 mA		"	4A			
			18								"							-18 mA		G			
	I _{IL1}	3009	19	GND	0.4 V						"							GND	5.5 V	1A	2/	2/	mA
	·IL1	"	20	5.5 V	0	0.4 V												"	"	1B		-	"
			21	GND		0. 4 V		0.4 V			,,									2A			
			22	5.5 V				0. 4 V	0.4 V								 			2B			
			23	5.5 V					0.4 V				0.4 V		-					3B			
			24	GND									0.4 V	0.4 V	-			-		3A			
														0.4 V		0.41/		-	-	3A 4B		-	
			25	5.5 V												0.4 V	0.41/			4B 4A		-	
			26	5.5 V													0.4 V	0.417					
	I _{IL2}		27	0.41/														0.4 V		G			-
			28	0.4 V	0.71/															S			
	I _{IH1}	3010	29	5.5 V	2.7 V															1A		20	μA
			30	GND		2.7 V														1B			
			31	5.5 V				2.7 V											"	2A		"	
		"	32	GND					2.7 V		"								"	2B			
		"	33	GND							"		2.7 V						"	3B			
			34	5.5 V										2.7 V					"	3A		"	
		"	35	GND							"					2.7 V			"	4B			"
		"	36	5.5 V							"						2.7 V		"	4A		"	
		"	37	GND							"							2.7 V		G			"
	I _{IH2}	3010	38	5.5 V	7.0 V															1A		100	"
		"	39	GND		7.0 V					"								"	1B	-		"
		"	40	5.5 V				7.0 V			-								"	2A		"	"
		"	41	GND					7.0 V		"								"	2B		"	"
		"	42	GND							"		7.0 V						"	3B			"
			43	5.5 V							"			7.0 V					"	3A		"	"
		"	44	GND							"					7.0 V			"	4B			
		"	45	5.5 V							"						7.0 V		"	4A		"	-
			46	GND							"							7.0 V		G			
	I _{IH3}	"	47	2.7 V							"								"	S		40	"
	I _{IH4}	"	48	7.0 V							"								"	S		200	"
	I _{OZH}		49	2.0 V		2.0 V	2.7 V				"							2.0 V	"	1Y		20	"
	0211		50	"					2.0 V	2.7 V								-		2Y		,	
			51	"							"	2.7 V	2.0 V						"	3Y			
			52	"							"				2.7 V	2.0 V			"	4Y			
	I _{OZL}	†	53	0.7 V	0.7 V	l	0.4 V												"	1Y		-20	
	'OZL		54	U.7 V	0.7 V	 	0.7 1	0.7 V		0.4 V						 				2Y		"	
			55	"				0.7 V		0¥ V	"	0.4 V		0.7 V		 				3Y			
			56	"		-					"	∪. + v		0.7 V	0.4 V	1	0.7 V		"	4Y			
	l	1	J0	l .	l	l	l	1				ı			U.4 V	1	U.7 V		1	41			

See footnotes at end of device type 07.

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TABLE III. Group A inspection for device type 07 - Continued. Terminal conditions (pins not designated may be high $\geq 2.0 \text{ V}$; low $\leq 0.7 \text{ V}$; or open).

						- 10	, i i i i i i i i i i i i i i i i i i i	condition	is (piris	Hot ucc	signated	i iliay b	e nign ≥				<i>i</i> Cii).						
		MIL-STD-	Cases E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16				
Subgroup	Symbol	883 method	Cases <u>1</u> / 2, X	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20	Measured terminal	Lin	nits	Unit
			Test no.	S	4.0	1B	41/	2.4	2B	2Y	GND	3Y	3B	3A	4Y	4B	4.0	G	17		Min	May	
	-	0044			1A	ID	1Y	2A	2B	_ Z î	GND	31	3D	ЗA	41	4B	4A		V _{CC}	41/		Max	
	los	3011	57	GND	GND		GND											GND		1Y	-30	-130	mA
	<u>3</u> /		58					GND		GND										2Y			
			59	"								GND		GND						3Y			
		"	60	"							"				GND		GND			4Y			"
	I _{CC1}	3005	61	5.5 V	5.5 V	5.5 V		5.5 V	5.5 V				5.5 V	5.5 V		5.5 V	5.5 V		"	V _{CC}		15	"
	I _{CC2}	"	62	GND	GND	GND		GND	GND		"		GND	GND		GND	GND			V _{cc}		9	
	I _{CC3}	"	63								"							5.5 V		V _{cc}		19	
2	Same to	ests, termina	al conditions	and limits	as subar	oup 1. exc	$ept T_c = +$	125°C and	V _{IC} tests	omitted.													
3	Same te	ests termina	al conditions	and limits	as subara	oun 1 exc	ent T ₀ = -5	55°C and \	tests or	mitted													
7	Func-	3014	64	В	B	В	H	В	B	Н	GND	Н	В	В	Н	В	В	В	5.0 V	All			
		3014	65	ا ا	В	A	Н	В	A	Н	UND "	H	A	В	H	A	В	"	J.U V	outputs			
Tc = 25°C			66							L	-	L			- !!		A	-	-	υσιραίδ			
1	tests				A		L	A			"			A	L					1			
1			67		В		Η.	В		H		Н		В	H		В			1	<u>4</u> /		
			68	Α	В	"	L	В		L		L	- "	В	L	-	В	"					
		"	69	"	Α	"	L	Α	"	L	"	L		Α	L	"	Α	"					
			70	"	Α	В	Н	Α	В	Н	"	Н	В	Α	Н	В	Α		"		1		
		"	71	"	В	В	Н	В	В	Н		Н	В	В	Н	В	В						
8	Repeat	subgroup 7	tests at T _C	= +125°C	and $T_c = -$	55°C																	
9	t _{PLH1}	3003	72	GND	IN		OUT				GND							GND	5.0 V	1A to 1Y	3	23	ns
Tc = 25°C		Fig. 4	73	5.0 V		IN	OUT				"							"		1B to 1Y			
10-20 0		"	74	GND				IN		OUT	"									2A to 2Y			
			75	5.0 V				1111	IN	OUT										2B to 2Y			
			76	5.0 V					IIN	001		OUT	IN	-					-	3B to 3Y	-	-	-
								ļ			"		IIN										
			77	GND								OUT		IN	OUT.					3A to 3Y			
			78	5.0 V											OUT	IN				4B to 4Y			
			79	GND											OUT		IN			4A to 4Y			
	t _{PHL1}		80	GND	IN		OUT				"									1A to 1Y			
			81	5.0 V		IN	OUT				"									1B to 1Y			"
			82	GND				IN		OUT										2A to 2Y			
			83	5.0 V					IN	OUT	"								"	2B to 2Y			"
		"	84	5.0 V							"	OUT	IN							3B to 3Y			"
		"	85	GND							"	OUT		IN					"	3A to 3Y			"
			86	5.0 V							"				OUT	IN		"		4B to 4Y		"	"
		"	87	GND							"				OUT		IN	"		4A to 4Y		"	"
1	t _{PLH5}	"	88	IN	5.0 V	GND	OUT				"							"		S to 1Y		26	
1		"	89	"				5.0 V	GND	OUT	"							"		S to 2Y		"	"
1		"	90	"							"	OUT	GND	5.0 V				"	"	S to 3Y	"	"	-
			91	"							"				OUT	GND	5.0 V		"	S to 4Y			
1	t _{PHL5}		92		GND	5.0 V	OUT			l	"			1	001	0.10	0.0 *			S to 1Y			
1	4PHL5		93	"	OIND	3.0 V	001	GND	5.0 V	OUT	-			 					-	S to 2Y		-	
1			94					GIVD	J.0 V	001		OUT	5.0 V	GND						S to 3Y			-
1								-		 	-	001	5.0 V	שאט	OUT	E 0 1/	CND		-				
	\vdash		95		OND		OUT	 		 	-	 		 	OUT	5.0 V	GND	IN.	<u> </u>	S to 4Y			
	t _{PZH3}		96	GND	GND		OUT	OND		OUT	-					ļ		IN "	<u> </u>	G to 1Y		35	
			97	- "				GND		OUT	<u> </u>	OUT		OND				-		G to 2Y			
			98					ļ		 		OUT		GND		 				G to 3Y			
1		"	99	"							"				OUT		GND	"		G to 4Y			
I	t _{PZL3}	"	100	5.0 V		5.0 V	OUT				"							"		G to 1Y	"	"	"
1		"	101	"					5.0 V	OUT	"								"	G to 2Y			
			102	"							"	OUT	5.0 V					"		G to 3Y		"	"
			103	"							"				OUT	5.0 V			"	G to 4Y			
			•					•		•		•				•		•	•		•		

MIL-M-38510/309E

See footnotes at end of device type 07.

TABLE III. Group A inspection for device type 07 - Continued.

Terminal conditions (pins not designated may be high $\geq 2.0 \text{ V}$; low $\leq 0.7 \text{ V}$; or open).

		MIL-STD-	Cases E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16				
Subgroup	Symbol	883 method	Cases <u>1</u> / 2, X	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20	Measured terminal	Lim	iits	Unit
			Test no.	S	1A	1B	1Y	2A	2B	2Y	GND	3Y	3B	3A	4Y	4B	4A	G	V _{cc}		Min	Max	1 '
9	t _{PHZ3}	3003	104	GND	GND		OUT				"							IN	"	G to 1Y	3	35	ns
Tc = 25°C		Fig. 4	105	"				GND		OUT	"								"	G to 2Y	"		"
		"	106	"							"	OUT		GND					"	G to 3Y			"
		"	107	"							"				OUT		GND		"	G to 4Y			
	t _{PLZ3}	"	108	5.0 V		5.0 V	OUT				"								"	G to 1Y		30	"
			109	"					5.0 V	OUT	"								"	G to 2Y			
		"	110	"							"	OUT	5.0 V						"	G to 3Y	"	"	"
		"	111	"							-				OUT	5.0 V				G to 4Y			

Same tests, terminal conditions and limits as subgroup 9, except $T_C = +125^{\circ}C$ and for the following: t_{PLH1} and $t_{PHL1} = 3$ to 35 ns; t_{PLH5} and $t_{PHL5} = 3$ to 39 ns; t_{PZH3} , t_{PZL3} , and $t_{PHZ3} = 3$ to 53 ns; $t_{PZL3} = 3$ to 45 ns.

Same tests, terminal conditions and limits as subgroup 10, except $T_C = -55^{\circ}C$.

1/ Case X and 2 pins not referenced are NC.

 $2/I_{IL}$ limits shall be as follows:

42

			Min/Max lin	nits (mA) for circ	uits		
Test	Α	В	С	D	E	F	G
I _{IL1}	15/38	16/40	20/44	0/30	0/20	12/36	0/15
I _{IL2} test 27	0/20	16/40	20/44	0/30	0/10	12/36	0/15
I _{IL2} test 28	0/20	32/80	32/80	0/60	0/10	24/72	0/15

 $3/I_{OS}$ limits for circuits B, C, D, F, and G are -15 to -100 mA.

 $\underline{4}$ / Inputs: A \geq 2.5 V minimum, B \leq 0.4 V maximum.

Outputs: Output voltages shall be either:

- a. H = 2.5 volts minimum and L = 0.4 volt maximum when using a high speed checker double comparator, or
- b. $H \ge 1.5$ volts and $L \le 1.5$ volts when using a high speed checker single comparator.
- c. Attributes data only is required for subgroups 7 and 8.

TABLE III. <u>Group A inspection for device type 08</u>. Terminal conditions (pins not designated may be high \geq 2.0 V; low \leq 0.7 V; or open).

						16	erminai d	conditio	ns (pins	not des	signated	ı may b	e nign ≥	2.0 V; 10	$5w \le 0.7$	v; or op	en).						
		MIL-STD-	Cases E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16				
Subgroup	Symbol	883 method	Cases <u>1</u> / 2, X	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20	Measured terminal	Lim	iits	Unit
			Test no.	1G	В	1C3	1C2	1C1	1C0	1Y	GND	2Y	2C0	2C1	2C2	2C3	Α	2G	V _{CC}		Min	Max	
1	V _{OH}	3006	1	0.7 V	0.7 V	100	102	101	2.0 V	-1 mA	GND		200	201	202	200	0.7 V	20	4.5 V	1Y	2.4	IVIGA	V
Tc = 25°C	*OH	"	2	0.7 V	0.7 V				2.0 1	1110	"	-1 mA	2.0 V				0.7 V	0.7 V	T.0 V	2Y	2.4		
10 - 23 0	V _{OL}	3007	3	0.7 V	2.0 V	0.7 V				4 mA		-1111/4	2.0 V				2.0 V	0.7 V	"	1Y	2.7	0.4	"
	V OL	3007	4	0.1 V	2.0 V	0.7 V				7 111/4		4 mA				0.7 V	2.0 V	0.7 V	"	2Y		0.4	
	V _{IC}		5	-18 mA	2.0 V							4111/1				0.7 V	2.0 V	0.7 V		1G		-1.5	
	VIC		6	-10 IIIA	-18 mA															В		-1.5	
			7		-10 111/4	-18 mA														1C3			
			8			-101117	-18 mA													1C2			
			9				-10 111/4	-18 mA												1C1			
			10					-10 1117	-18 mA											1C0			
			11						-10 IIIA				-18 mA							2C0			
			12										10 110 (-18 mA						2C1			
			13											-101117	-18 mA					2C2			
			14								"				101111	-18 mA				2C3			
			15													-101117	-18 mA			A A			
			16														10 110 1	-18 mA		2G			
	I _{IL1}	3009	17	0.4 V							"							10 110 1	5.5 V	1G	2/	2/	mA
	'IL1	"	18	0.4 1	0.4 V														U.U V	В	==	===	"
		"	19	GND	5.5 V	0.4 V											5.5 V		"	1C3		"	"
			20	UIVD "	5.5 V	0. 4 V	0.4 V										GND		"	1C2		"	"
			21	"	GND		0. + v	0.4 V									5.5 V		"	1C1		"	"
			22	"	GIVD "			0.4 V	0.4 V								GND			1C0			
			23		"				0. 4 V				0.4 V				GND	GND	"	2C0		"	"
			24		"								0.4 V	0.4 V			5.5 V	UIVD		2C1			
		"	25		5.5 V									0.4 V	0.4 V		GND			2C2		"	
			26		5.5 V										0.4 V	0.4 V	5.5 V		"	2C3		"	
			27		3.5 V											0. 4 V	0.4 V			A A			
			28														0. + v	0.4 V		2G		"	"
	I _{IH1}	3010	29	2.7 V														0. + v		1G		20	μА
	'IH1	"	30	2.7 V	2.7 V															В		"	μΛ
			31		GND	2.7 V	"										GND		"	1C3		"	
			32		GND	Z.1 V	2.7 V										5.5 V		"	1C2		"	"
		"	33		5.5 V		Z.1 V	2.7 V									GND			1C1		"	
			34		J.J V			Z.1 V	2.7 V								5.5 V			1C0			
			35		"				Z.1 V				2.7 V				5.5 V			2C0			
		"	36		"	1					"		Z.1 V	2.7 V			GND			2C1			
		"	37		GND	 								/ V	2.7 V		5.5 V			2C2		"	
		"	38		GND	1									2.1 V	2.7 V	GND			2C3		"	
		"	39		0.10	1										Z.1 V	2.7 V			A A			
		"	40			1											2.7 V	2.7 V		2G			
	I _{IH2}	"	41	7.0 V	1	1												Z.1 V		1G		100	
	'IH2	"	42	7.0 0	7.0 V	1														В		"	
		"	43		GND	7.0 V											GND		"	1C3		"	
		"	44		GND	7.0 0	7.0 V										5.5 V		"	1C2		"	
		"	45		5.5 V	 	7.5 V	7.0 V									GND			1C1		"	
		"	46		3.5 V	 			7.0 V								5.5 V			1C0			
		"	47	l		1			7.0 1				7.0 V	l	1		5.5 V			2C0			
		"	48		"	1					"		7.0 V	7.0 V			GND			2C1			
		"	49		GND	1								7.0 V	7.0 V		5.5 V			2C2		"	
		"	50	 	GND	 					"			 	7.0 0	7.0 V	GND		"	2C3		"	"
		"	51		CIAD	1					"					7.0 V	7.0 V			A			
		"	52	 	 	 					"			 			7.0 V	7.0 V	-	2G			
L	i	l	JZ	l .	1	<u> </u>			l					l	l	L		7.U V	L	20	L		

See footnotes at end of device type 08.

TABLE III. Group A inspection for device type 08 - Continued. Terminal conditions (pins not designated may be high ≥ 2.0 V; low ≤ 0.7 V; or open).

						16	erminai (conditio	ns (pins	not des	signated	ı may b	e high ≥	2.0 V; K	$W \leq U.7$	v; or op	en).						
		MIL-STD-	Cases E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16				
Subgroup	Symbol	883 method	Cases <u>1</u> / 2, X	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20	Measured terminal	Lin	nits	Unit
			Test no.	1G	В	1C3	1C2	1C1	1C0	1Y	GND	2Y	2C0	2C1	2C2	2C3	Α	2G	V_{CC}		Min	Max	
1	I _{OZH}		53	2.0 V	0.7 V				0.7 V	2.7 V	GND						0.7 V		5.5 V	1Y		20	μA
Tc = 25°C			54		0.7 V						"	2.7 V	0.7 V				0.7 V	2.0 V	"	2Y		20	<u>"</u>
	I _{OZL}		55	2.0 V	2.0 V	2.0 V				0.4 V	"						2.0 V		"	1Y		-20	"
	OZL		56		2.0 V						"	0.4 V				2.0 V	2.0 V	2.0 V	"	2Y		-20	"
	los	3011	57	GND	GND				5.5 V	GND							GND		"	1Y	-30	-130	mA
	3/	3011	58		"						"	GND	5.5 V				"	GND	"	2Y	-30	-130	
	I _{CC1}	3005	59	GND	"	GND	GND	GND	GND		"		GND	GND	GND	GND		GND	"	V _{CC}		12	
	I _{CC2}	3005	60	5.5 V	"	GND	GND	GND	GND		"		GND	GND	GND	GND		5.5 V	"	V _{CC}		14	
2			al conditions		s as subgro					omitted.											1		
3			al conditions																				
7	Func-	3014	61	В	В	A	A	A	В	L	GND	L	В	Α	Α	Α	В	В	5.0 V	All			
Tc = 25°C	tional	"	62	-	-	В	В	В	В	Ē	"	Ē	В	В	В	В	-	-	"	Outputs	1		
.0-200	tests		63			-	-	-	A	Н		Н	A	"					"	"	1		
	10010		64	"	"	"	"	"	"	Ĺ	"	i	"	"			Α			"	1		
			65	"	"	"	"	Α	"	H	"	H	"	Α			A			"	1		
			66	"	"	"	"	"	"	H	"	H	"	"			B			"	1		
			67	"	Α	"	"	"	"	i i	"	i		"			-			"	1		
			68	"	"	"	Α	"	"	H	"	H	"	"	Α					"	1	<u>4</u> /	
			69	"	"	"	"	"	"		"			"	"		Α			"	1	2/	
			70	"	"	Α	"	"	"	H	"	H	"	"		Α	A			"	1		
8	Reneat	subaroup 7	tests at Tc	– +125°C	and Tc = -												, ,,			l .	1		
9	t _{PLH1}	3003	71	GND	GND				IN	OUT	GND						GND		5.0 V	1C0 to 1Y	3	30	ns
Tc = 25°C	*FLHI	(Fig. 4)	72	"	GND			IN		"	"						5.0 V		"	1C1 to 1Y	ı.	"	"
10 = 23 0		(119.4)	73	"	5.0 V		IN			"	"						GND			1C2 to 1Y			
			74	"	5.0 V	IN				"	"						5.0 V			1C3 to 1Y			
			75		GND						"	OUT	IN				GND	GND		2C0 to 2Y		"	
			76		GND						"	"		IN			5.0 V	"		2C1 to 2Y			
			77		5.0 V						"				IN		GND			2C2 to 2Y			
			78		5.0 V						"					IN	5.0 V			2C3 to 2Y			
	t _{PHL1}	"	79	GND	GND				IN	OUT	"						GND			1C0 to 1Y		25	"
	*FILI	"	80	"	GND			IN	<u> </u>		"						5.0 V			1C1 to 1Y	"	"	"
		"	81	"	5.0 V		IN				"						GND		-	1C2 to 1Y	"	"	"
		"	82	"	5.0 V	IN	· · · ·			OUT	"						5.0 V		-	1C3 to 1Y	"		"
		"	83		GND						"	OUT	IN				GND	GND		2C0 to 2Y	"	"	
		"	84		GND						"	"		IN			5.0 V	"		2C1 to 2Y	"	"	
		"	85		5.0 V						"			L	IN		GND			2C2 to 2Y		"	
		"	86		5.0 V						"					IN	5.0 V			2C3 to 2Y		"	
	t _{PLH5}	"	87	GND	GND			5.0 V	GND	OUT	"	1				· · · ·	IN		"	A to 1Y		50	ı
	*FLHS	"	88	0.,0	GND			0.0 .	0.,0		"	OUT	GND	5.0 V			IN	GND		A to 2Y		"	
		"	89	GND	IN		5.0 V		GND	OUT	"	1					GND			B to 1Y		"	
		"	90	0	IN		0.0.		0		"	OUT	GND		5.0 V		GND	GND		B to 2Y			
	t _{PHL5}		91	GND	GND			GND	5.0 V	OUT	"		0.,5		0.0 .		IN	0.10	"	A to 1Y		37	"
	PHLS	"	92	0.10	GND			0.10	0.0 v		"	OUT	5.0 V	GND			IN	GND		A to 2Y		"	
		"	93	GND	IN		GND		5.0 V	OUT	"		0.0 ¥	0110		1	GND	0.10		B to 1Y			-
			94	0.10	IN		0.10		0.0 1		"	OUT	5.0 V		GND	†	GND	GND		B to 2Y			
			J-7	L	11.4	L	L	L	l	l	l	001	J.U V	l	OIVD	·	CIAD	OND	1	DIOZI	<u> </u>		

See footnotes at end of device type 08.

TABLE III. Group A inspection for device type 08 - Continued.

Terminal conditions (pins not designated may be high $\geq 2.0 \text{ V}$; low $\leq 0.7 \text{ V}$; or op-	Terminal conditions	s not designated may	v be high $\geq 2.0 \text{ V}$: low ≤ 0.7 V: or open)
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Subgroup		MIL-STD- 883 method	Cases E, F Cases <u>1</u> / 2, X	2	3	3	5	7	8	9	10	12	13	11	12	17	18	15	16 20	Measured terminal	Lim	iits	Unit
			Test no.	1G	В	1C3	1C2	1C1	1C0	1Y	GND	2Y	2C0	2C1	2C2	2C3	Α	2G	V_{cc}		Min	Max	
9	t _{PZH3}	3003	95	IN	5.0 V	5.0 V				OUT	GND						5.0 V		5.0 V	1G to 1Y	3	46	ns
Tc = 25°C		(Fig. 4)	96		5.0 V						"	OUT				5.0 V	5.0 V	IN		2G to 2Y		46	"
	t _{PZI 3}	"	97	IN	GND				GND	OUT							GND			1G to 1Y	"	28	"
		"	98		GND						"	OUT	GND				GND	IN		2G to 2Y	"	28	"
	t _{PHZ3}	"	99	IN	5.0 V	5.0 V				OUT	"						5.0 V			1G to 1Y		46	"
		"	100		5.0 V						"	OUT				5.0 V	5.0 V	IN		2G to 2Y		46	"
	t _{PI 73}	"	101	IN	GND				GND	OUT	"						GND			1G to 1Y		32	
		"	102		GND						"	OUT	GND				GND	IN		2G to 2Y		32	

Same tests, terminal conditions and limits as subgroup 9, except $T_C = +125$ °C and limits as follows:

 $t_{PLH1} = 3$ to 45 ns; $t_{PHL1} = 3$ to 38 ns; $t_{PLH5} = 3$ to 75 ns; $t_{PHL5} = 3$ to 56 ns;

 $t_{PZH3} = 3$ to 69 ns; $t_{PZL3} = 3$ to 42 ns, and $t_{PHZ3} = 3$ to 69 ns; $t_{PLZ3} = 3$ to 48 ns.

11 Same tests, terminal conditions and limits as subgroup 10, except T_C = -55°C.

1/ Case X and 2 pins not referenced are NC.

$2/I_{IL}$ limits shall be as follows:

45

			Min/Ma	ax limits (mA) for	circuits		
Test	Α	В	С	D	Е	F	G
I _{IL1}	18 through 27 12/36 except test 28 and 17 001/15	12/36	12/36	03/30	Test 18 and 27 12/36 Test 17 and 28 16/40 Tests 19 through 26 16/40	12/36	0/15

3/ Ios limits for circuits B, D, E, F, and G are -15 to -100 mA.

 $\underline{4}/$ Inputs: $A \geq 2.4 \ V$ minimum, $B \leq 0.4 \ V$ maximum.

Outputs: Output voltages shall be either:

- a. H = 2.5 volts minimum and L = 0.4 volt maximum when using a high speed checker double comparator, or
- b. $H \ge 1.5$ volts and $L \le 1.5$ volts when using a high speed checker single comparator.
- c. Attributes data only is required for subgroups 7 and 8.

TABLE III. <u>Group A inspection for device type 09</u>. Terminal conditions (pins not designated may be high \geq 2.0 V; low \leq 0.7 V; or open).

						16	erminai (conditio	ns (pins	not des	signated	⊢may b	e high ≥	2.0 V; K	0.7	v; or op	en).						
		MIL-STD-	Cases E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16				
Subgroup	Symbol	883 method	Cases <u>1</u> / 2, X	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20	Measured terminal	Lin	nits	Unit
			Test no.	B2	A2	A1	B1	C2	D2	D1	GND	C1	WS	CP	QD	QC	QB	QA	V _{CC}		Min	Max	
1	V _{OH}	3006	1		2.0 V						GND		2.0 V	2/				4 mA	4.5 V	QA	2.5		V
Tc = 25°C		"	2	2.0 V							"			"			4 mA		"	QB	"		"
		"	3					2.0 V			=			"		4 mA			-	QC	-		
		"	4						2.0 V		=			"	4 mA				-	QD	-		"
	V _{OL}	3007	5		0.7 V						"			"				4.0 mA		QA		0.4	
		"	6	0.7 V							"			"			4.0 mA			QB			
		"	7					0.7 V			"			"		4.0 mA				QC			
		"	8						0.7 V		"			"	4.0 mA					QD			
	Vic		9	-18 mA							"									B2		-1.5	
			10		-18 mA						"								"	A2			
			11			-18 mA					"									A1			
			12				-18 mA				"									B1			
			13					-18 mA			"								"	C2			
			14						-18 mA		"									D2			
			15							-18 mA	"								"	D1		"	"
			16								"	-18 mA							"	C1		"	"
	1	1	17								"		-18 mA						"	WS		"	"
	1	1	18								"			-18 mA					"	CP		"	"
	I _{IL1}	3009	19	0.4 V							"		5.5 V						5.5 V	B2	<u>3</u> /	<u>3</u> /	mA
		"	20		0.4 V						"		5.5 V						"	A2	"		
		"	21			0.4 V					"		GND						"	A1	-	"	
		"	22				0.4 V				"		GND						"	B1		"	"
		"	23					0.4 V			"		5.5 V						"	C2			
		"	24						0.4 V		"		5.5 V						"	D2			
		"	25							0.4 V	-		GND						"	D1		"	
		"	26								"	0.4 V	GND							C1			
			27								"		0.4 V						"	WS	"	"	"
		"	28								"			0.4 V					"	CP		"	
	<u> </u>	3010	29	2.7 V							"		GND							B2		20	
	I _{IH1}	3010		2.7 V	271/								GND						,	A2		20	μA "
			30		2.7 V	2.7 V													,	A2 A1			
			31			2.7 V	0.71/				-		5.5 V									-	
			32				2.7 V	271/			,		5.5 V							B1		-	
			33					2.7 V	271/				GND						,	C2			
		"	34	 	1	 		1	2.7 V	2711	-		GND		 	1	 		-	D2		-	
	1	,,	35 36	 	!	-		 	-	2.7 V		2.7 V	5.5 V 5.5 V	 	-	 	-		-	D1 C1	 	-	-
1		,,	37		<u> </u>	-						Z.1 V	2.7 V			-				WS			-
		,,	38		1	<u> </u>					,,		Z./ V	2.7 V		 			-			-	-
	1	1	38	1					1					2./ V	1		1			CP			
	I _{IH2}	"	39	5.5 V							"		GND						"	B2		100	"
	"12	"	40		5.5 V						"		GND						"	A2		"	"
		"	41			5.5 V					"		5.5 V						"	A1		"	"
		"	42		1	1	5.5 V				"		5.5 V						"	B1		"	
		"	43		1			5.5 V			"		GND						"	C2		"	
		"	44		1				5.5 V		"		GND						"	D2		"	"
		"	45		1					5.5 V	"		5.5 V						"	D1			
		"	46		1						"	5.5 V	"							C1			"
		"	47		1						"					†				WS		"	
		"	48								"			5.5 V						CP CP			
	Ios	3011	49			5.5 V					"		GND	2/				GND		QA	-15	-100	mA
		"	50				5.5 V				"			"			GND			QB	"		"
		"	51								"	5.5 V		"		GND			"	QC			"
		"	52							5.5 V	"			"	GND				"	QD		"	"
	I _{CC1}	3005	53	GND	GND	GND	GND	GND	GND	GND		GND	"	<u>4</u> /					"	V _{cc}		21	"

See footnotes at end of device type 09.

TABLE III. Group A inspection for device type 09 - Continued.

Terminal conditions (pins not designated may be high > 2.0 V: low < 0.7 V: or open).

						16	Hillinai	Conditio	ris (piris	not des	signateu		e high ≥	2.0 V, I	JW ≥ U.7	ν, οι ορ							
		MIL-STD-	Cases E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16				
Subgroup Sy	/mbol	883 method	Cases <u>1</u> / 2, X	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20	Measured terminal	Lim	nits	Unit
			Test no.	B2	A2	A1	B1	C2	D2	D1	GND	C1	WS	CP	QD	QC	QB	QA	V _{CC}		Min	Max	
2 Sa	ame te	sts termina	al conditions	and limits	as subara	nun 1 exce	ent To = +	125°C and	V _{io} tests	omitted	1			l		1	l .			1			
			al conditions																				
	unc-	3014	54	A	A	B B	В	A	A	В	GND	В	В	Α				1	5.0 V	All			
Tc = 25°C tio		"	55	"	"	"	"	- "	"	"	"	-	=	В	-	-	-	-	U.U V	ouputs			
	ests		56											A					"	"			
10	-	"	57		"	Α	Α	"	"	Α	"	Α		A						"			
	F	"	58		"	-	-	"	"	"	"			В	Н	Н	Н	Н		"			
	F	"	59		"	"	"	"	"	"	"			A				- ;		"			
	-	"	60		"	В	В	"	"	В	"	В		A						"			
	-	"	61		"	В	В	"	"	В	"	В	"	В				1		"			
	-	"	62	"	"	A	A	"	"	A	"	A		"	-	-	-	-		"		5/	
	-	"	63	"	"	В	В	"	"	В	"	В		"						"		<u> </u>	
	F	"	64	"	"	"	"	"	"	"	"	"		Α					"	"			
	F	"	65	"	"	"	"	"	"	"	"		Α	"					"	"			
	F	"	66	"	"	Α	Α	"	"	Α	"	Α	"	"			"		"	"			
	F	"	67	"	"	"	"	"	"	"	"	"		В	Н	Н	Н	Н	"	"			
	<u> </u>	"	68		"	"	"	"	"	"	"			A			"		"	"			
	F	"	69	В	В	"	"	В	В	"	"	"		Α	"		"		"	"			
	F	"	70	В	В	"	"	В	В	"	"	"	"	В	L	L	L	L	"	"			
	F	"	71	Α	Α	"	"	Α	Α	"	"	"		"	"	"	"		"	"			
		"	72	В	В		"	В	В	"	"			"					"	"			
8 Re	epeat s	subgroup 7	tests at T _C =	+125°C	and T _C = -	55°C.																	
	PLH1	3003	73		IN						GND		5.5 V	IN				OUT	5.0 V	CP to QA	3	33	ns
Γc = 25°C	-	Fig. 4	74	IN							"		"	"			OUT		"	CP to QB		"	"
	F	"	75					IN			"			"		OUT				CP to QC			
	-	"	76						IN		"			"	OUT								
<u> </u>		"	77		IN						,			,,				OUT		CP to QD		37	
LP.	PHL1				IIN													001		CP to QA		31	
		"	78	IN							"			"			OUT		"	CP to QB		"	
	Γ	"	79					IN			"	·		"		OUT			"	CP to QC		"	"
	Ī	"	80						IN		"		"	"	OUT				"	CP to QD	"	"	"
			al conditions that = 3 to 48		as subgro	oup 9, exce	ept T _C = +	125°C and	limits as f	ollows:				ı		ı	ı		1				

1/ Case X and 2 pins not referenced are NC.
 2/ Apply normal clock pulse.
 3/ I_{IL} limits shall be as follows:

Same tests, terminal conditions and limits as subgroup 10, except $T_C = -55^{\circ}C$.

			Min/Max I	limits (mA) for circu	its		
Test	Α	В	С	D	Е	F	G
I _{IL1}	16/40	-	-	16/40 except	16/40 except	12/36	-
				03/30 test 27 and 28	12/36 test 27 and 28		

 $[\]begin{array}{ll} \underline{4}/ & \text{Apply} \geq 3.0 \text{ V pulse, then ground, then measure.} \\ \underline{5}/ & \text{Inputs: } A \geq 2.5 \text{ V minimum, } B \leq 0.4 \text{ V maximum.} \\ & \text{Outputs: } H \geq 1.5 \text{ volts, } L \leq 1.5. \end{array}$

5. PACKAGING

5.1 <u>Packaging requirements.</u> For acquisition purposes, the packaging requirements shall be as specified in the contract or order (see 6.2). When actual packaging of materiel is to be performed by DoD personnel, these personnel need to contact the responsible packaging activity to ascertain requisite packaging requirements. Packaging requirements are maintained by the Inventory Control Point's packaging activity within the Military Department of Defense Agency, or within the Military Department's System Command. Packaging data retrieval is available from the managing Military Department's or Defense Agency's automated packaging files, CD-ROM products, or by contacting the responsible packaging activity.

6. NOTES

- 6.1 <u>Intended use.</u> Microcircuits conforming to this specification are intended for original equipment design applications and logistic support of existing equipment.
 - 6.2 Acquisition requirements. Acquisition documents should specify the following:
 - a. Title, number, and date of the specification.
 - b. Complete part number (see 1.2).
 - c. Requirements for delivery of one copy of the quality conformance inspection data pertinent to the device inspection lot to be supplied with each shipment by the device manufacturer, if applicable.
 - d. Requirements for certificate of compliance, if applicable.
 - e. Requirements for notification of change of product or process to contracting activity in addition to notification to the qualifying activity, if applicable.
 - f. Requirements for failure analysis (including required test condition of method 5003 of MIL-STD-883), corrective action, and reporting of results, if applicable.
 - g. Requirements for product assurance options.
 - h. Requirements for special carriers, lead lengths, or lead forming, if applicable. These requirements should not affect the part number. Unless otherwise specified, these requirements will not apply to direct purchase by or direct shipment to the Government.
 - j. Requirements for "JAN" marking.
- 6.3 <u>Superseding information.</u> The requirements of MIL-M-38510 have been superseded to take advantage of the available Qualified Manufacturer Listing (QML) system provided by MIL-PRF-38535. Previous references to MIL-M-38510 in this document have been replaced by appropriate references to MIL-PRF-38535. All technical requirements now consist of this specification and MIL-PRF-38535. The MIL-M-38510 specification sheet number and PIN have been retained to avoid adversely impacting existing government logistics systems and contractor's parts lists.
- 6.4 <u>Qualification</u>. With respect to products requiring qualification, awards will be made only for products which are, at the time of award of contract, qualified for inclusion in Qualified Manufacturers List QML-38535 whether or not such products have actually been so listed by that date. The attention of the contractors is called to these requirements, and manufacturers are urged to arrange to have the products that they propose to offer to the Federal Government tested for qualification in order that they may be eligible to be awarded contracts or purchase orders for the products covered by this specification. Information pertaining to qualification of products may be obtained from DSCC-VQ, 3990 E. Broad Street, Columbus, Ohio 43123-1199.

6.5 <u>Abbreviations, symbols, and definitions.</u> The abbreviations, symbols, and definitions used herein are defined in MIL-PRF-38535, MIL-HDBK-1331, and as follows:

GND	Ground zero voltage potential. Voltage level at an input terminal. Input clamp voltage. Current flowing into an input terminal. Output disable time (of a three-state output) from high level. The time between the specified reference points on the input
t _{PLZ}	and output voltage waveforms with the three-state output changing from the defined high level to a high-impedance (off) state. Output disable time (of a three-state output) from low level. The time between the specified reference points on the input and output voltage waveforms with the three-state output changing from the defined low level to a high-impedance (off) state.
t _{PZH}	Output enable time (of a three-state output) to high level. The time between the specified reference points on the input and output voltage waveforms with the three-state output changing
t _{PZL}	from a high-impedance (off) state to the defined low level. Output enable time (of a three-state output) to low level. The time between the specified reference points on the input and output voltage waveforms with the three-state output changing from a high-impedance (off) state to the defined low level.

- 6.6 <u>Logistic support.</u> Lead materials and finishes (see 3.4) are interchangeable. Unless otherwise specified, microcircuits acquired for Government logistic support will be acquired to device class B (see 1.2.2), lead material and finish A (see 3.4). Longer length leads and lead forming should not affect the part number.
- 6.7 <u>Substitutability.</u> The cross-reference information below is presented for the convenience of users. Microcircuits covered by this specification will functionally replace the listed generic-industry type. Generic-industry microcircuit types may not have equivalent operational performance characteristics across military temperature ranges or reliability factors equivalent to MIL-M-38510 device types and may have slight physical variations in relation to case size. The presence of this information should not be deemed as permitting substitution of generic-industry types for MIL-M-38510 types or as a waiver of any of the provisions of MIL-PRF-38535.

Military device	Generic-industry
type	type
01	54LS151
02	54LS153
03	54LS157
04	54LS158
05	54LS251
06	54LS257B
07	54LS258B
08	54LS253
09	54LS298

6.8 <u>Manufacturers' designation.</u> Manufacturers' circuits, which form a part of this specification, are designated as shown in table IV herein.

TABLE IV. Manufacturer's designator.

				CIRCUITS			
	Α	В	С	D	Е	F	G
Device type	Texas Instruments	Advanced Micro Devices	Raytheon	Signetics	Motorola	Fairchild	National
01	X	X	Χ	Х	Χ	Χ	X
02	Χ	X	Χ	Χ	Χ	Χ	Χ
03	X	X	Χ	X	Χ	X	X
04	Χ	X	Χ	Χ	Χ	Χ	Χ
05	X	X	Χ	Χ	X	Χ	Χ
06	X	X	Χ	Χ	X	Χ	Χ
07	X	X	Χ	Х	Χ	Χ	X
08	Х	Х	Χ	Х	Χ	Х	X
09	Χ	X	Χ	Χ	Χ	Χ	Χ

^{6.9 &}lt;u>Changes from previous issue</u>. Asterisks are not used in this revision to identify changes with respect to the previous issue due to the extensiveness of the changes.

Custodians:

Army - CR

Navy - EC

Air Force - 11

DLA - CC

Preparing activity:

DLA - CC

(Project 5962-1958)

Review activities:

Army - MI, SM

Navy - AS, CG, MC, SH, TD

Air Force - 03, 19, 99

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